FAMILY OF WIDE-BANDWIDTH HIGH-OUTPUT-DRIVE SINGLE SUPPLY OPERATIONAL AMPLIFIERS

Check for Samples: TLC080 , TLC081, TLC082, TLC083, TLC084, TLC085, TLC08xA

FEATURES

- **Wide Bandwidth: 10 MHz**
- **High Output Drive:**
  - **I_{OH}: 57 mA at V_{DD} – 1.5 V**
  - **I_{OL}: 55 mA at 0.5 V**
- **High Slew Rate:**
  - **SR+: 16 V/µs**
  - **SR−: 19 V/µs**
- **Wide Supply Range: 4.5 V to 16 V**
- **Supply Current: 1.9 mA/Channel**
- **Ultralow Power Shutdown Mode:**
  - **I_{DD}: 125 µA/Channel**
- **Low Input Noise Voltage: 8.5 nV$\sqrt{Hz}$**
- **Input Offset Voltage: 60 µV**
- **Ultra-Small Packages:**
  - **8- or 10-Pin MSOP (TLC080/1/2/3)**
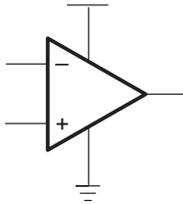
DESCRIPTION

The first members of TI's new BiMOS general-purpose operational amplifier family are the TLC08x. The BiMOS family concept is simple: provide an upgrade path for BiFET users who are moving away from dual-supply to single-supply systems and demand higher ac and dc performance. With performance rated from 4.5 V to 16 V across commercial (0°C to 70°C) and an extended industrial temperature range (–40°C to 125°C), BiMOS suits a wide range of audio, automotive, industrial, and instrumentation applications. Familiar features like offset nulling pins, and new features like MSOP PowerPAD™ packages and shutdown modes, enable higher levels of performance in a variety of applications.

Developed in TI's patented LBC3 BiCMOS process, the new BiMOS amplifiers combine a very high input impedance, low-noise CMOS front end with a high-drive bipolar output stage, thus providing the optimum performance features of both. AC performance improvements over the TL08x BiFET predecessors include a bandwidth of 10 MHz (an increase of 300%) and voltage noise of 8.5 nV/$\sqrt{Hz}$ (an improvement of 60%). DC improvements include an ensured V_{ICR} that includes ground, a factor of 4 reduction in input offset voltage down to 1.5 mV (maximum) in the standard grade, and a power supply rejection improvement of greater than 40 dB to 130 dB. Added to this list of impressive features is the ability to drive ±50-mA loads comfortably from an ultrasmall-footprint MSOP PowerPAD package, which positions the TLC08x as the ideal high-performance general-purpose operational amplifier family.

FAMILY PACKAGE TABLE

DEVICE	NO. OF CHANNELS	PACKAGE TYPES					UNIVERSAL EVM BOARD
		MSOP	PDIP	SOIC	TSSOP	SHUTDOWN	
TLC080	1	8	8	8	—	Yes	Refer to the EVM Selection Guide (Lit# SLOU060)
TLC081	1	8	8	8	—		
TLC082	2	8	8	8	—	—	
TLC083	2	10	14	14	—	Yes	
TLC084	4		14	14	20	—	
TLC085	4		16	16	20	Yes	

⚠ Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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All other trademarks are the property of their respective owners.

TLC080 and TLC081 AVAILABLE OPTIONS

T_A	PACKAGED DEVICES			
	SMALL OUTLINE (D)[1]	SMALL OUTLINE (DGN)[1]	SYMBOL	PLASTIC DIP (P)
0°C to 70°C	TLC080CD	TLC080CDGN	xxTIACW	TLC080CP
	TLC081CD	TLC081CDGN	xxTIACY	TLC081CP
−40°C to 125°C	TLC080ID	TLC080IDGN	xxTIACX	TLC080IP
	TLC081ID	TLC081IDGN	xxTIACZ	TLC081IP
	TLC080AID	—	—	TLC080AIP
	TLC081AID	—	—	TLC081AIP

(1) This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLC080CDR).

TLC082 and TLC083 AVAILABLE OPTIONS

T_A	PACKAGED DEVICES						
	SMALL OUTLINE (D)[1]	MSOP				PLASTIC DIP (N)	PLASTIC DIP (P)
		(DGN)[1]	SYMBOL[2]	(DGQ)[1]	SYMBOL[2]		
0°C to 70°C	TLC082CD	TLC082CDGN	xxTIADZ	—	—	—	TLC082CP
	TLC083CD	—	—	TLC083CDGQ	xxTIAEB	TLC083CN	—
−40°C to 125°C	TLC082ID	TLC082IDGN	xxTIAEA	—	—	—	TLC082IP
	TLC083ID	—	—	TLC083IDGQ	xxTIAEC	TLC083IN	—
	TLC082AID	—	—	—	—	—	TLC082AIP
	TLC083AID	—	—	—	—	TLC083AIN	—

(1) This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLC082CDR).
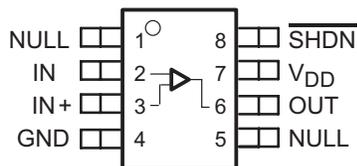(2) xx represents the device date code.

TLC084 and TLC085 AVAILABLE OPTIONS

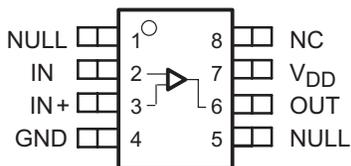| T_A	PACKAGED DEVICES		
	SMALL OUTLINE (D)[1]	PLASTIC DIP (N)	TSSOP (PWP)[1]
0°C to 70°C	TLC084CD	TLC084CN	TLC084CPWP
	TLC085CD	TLC085CN	TLC085CPWP
−40°C to 125°C	TLC084ID	TLC084IN	TLC084IPWP
	TLC085ID	TLC085IN	TLC085IPWP
	TLC084AID	TLC084AIN	TLC084AIPWP
	TLC085AID	TLC085AIN	TLC085AIPWP

(1) This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLC084CDR).

For the most current package and ordering information, see the Package Option Addendum at the end of this data sheet, or see the TI web site at www.ti.com.
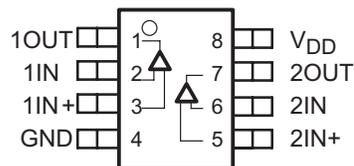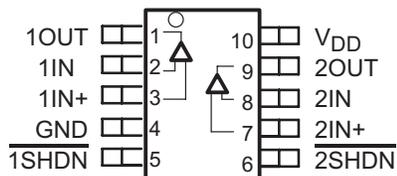
Product Folder Link(s): *TLC080 TLC081 TLC082 TLC083 TLC084 TLC085 TLC08xA*

TLC080
D, DGN, OR P PACKAGE
(TOP VIEW)

NULL	1	8	$\overline{SHDN}$
IN–	2	7	V_{DD}
IN+	3	6	OUT
GND	4	5	NULL

TLC081
D, DGN, OR P PACKAGE
(TOP VIEW)

NULL	1	8	NC
IN–	2	7	V_{DD}
IN+	3	6	OUT
GND	4	5	NULL

TLC082
D, DGN, OR P PACKAGE
(TOP VIEW)

1OUT	1	8	V_{DD}
1IN–	2	7	2OUT
1IN+	3	6	2IN–
GND	4	5	2IN+

TLC083
DGQ PACKAGE
(TOP VIEW)

1OUT	1	10	V_{DD}
1IN–	2	9	2OUT
1IN+	3	8	2IN–
GND	4	7	2IN+
$\overline{1SHDN}$	5	6	$\overline{2SHDN}$

TLC083
D OR N PACKAGE
(TOP VIEW)

1OUT	1	14	V_{DD}
1IN–	2	13	2OUT
1IN+	3	12	2IN–
GND	4	11	2IN+
NC	5	10	NC
$\overline{1SHDN}$	6	9	$\overline{2SHDN}$
NC	7	8	NC
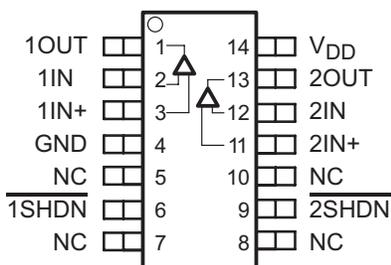
TLC084
D OR N PACKAGE
(TOP VIEW)

1OUT	1	14	4OUT
1IN–	2	13	4IN–
1IN+	3	12	4IN+
V_{DD}	4	11	GND
2IN+	5	10	3IN+
2IN–	6	9	3IN–
2OUT	7	8	3OUT
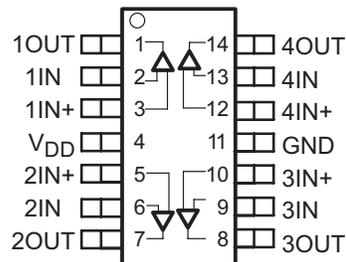
TLC084
PWP PACKAGE
(TOP VIEW)

1OUT	1	20	4OUT
1IN–	2	19	4IN–
1IN+	3	18	4IN+
VDD	4	17	GND
2IN+	5	16	3IN+
2IN–	6	15	3IN–
2OUT	7	14	3OUT
NC	8	13	NC
NC	9	12	NC
NC	10	11	NC
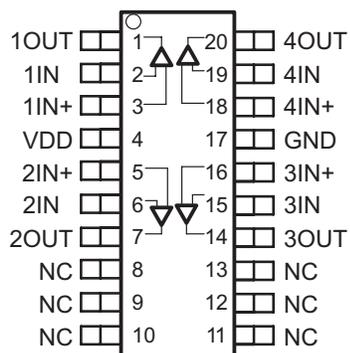
TLC085
D OR N PACKAGE
(TOP VIEW)

1OUT	1	16	4OUT
1IN–	2	15	4IN–
1IN+	3	14	4IN+
V_{DD}	4	13	GND
2IN+	5	12	3IN+
2IN–	6	11	3IN–
2OUT	7	10	3OUT
$\overline{1/2SHDN}$	8	9	$\overline{3/4SHDN}$
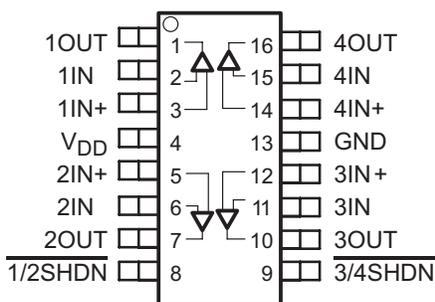
TLC085
PWP PACKAGE
(TOP VIEW)

1OUT	1	20	4OUT
1IN–	2	19	4IN–
1IN+	3	18	4IN+
VDD	4	17	GND
2IN+	5	16	3IN+
2IN–	6	15	3IN–
2OUT	7	14	3OUT
$\overline{1/2SHDN}$	8	13	$\overline{3/4SHDN}$
NC	9	12	NC
NC	10	11	NC
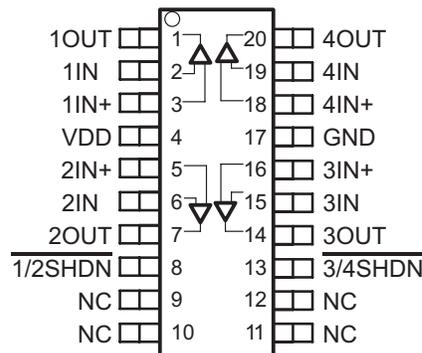
NC - No internal connection

TYPICAL PIN 1 INDICATORS

Pin 1 Printed or Molded Dot | Pin 1 Stripe | Pin 1 Bevel Edges | Pin 1 Molded "U" Shape

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TLC080 , TLC081, TLC082
TLC083, TLC084, TLC085, TLC08xA
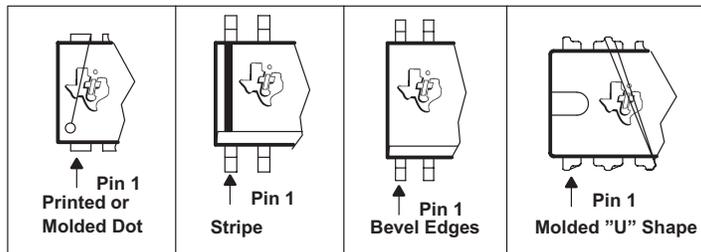
ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)[1]

		VALUE	UNIT
Supply voltage, V_{DD}[2]		17	V
Differential input voltage range, V_{ID}		±VDD	
Continuous total power dissipation		See Dissipation Rating Table	
Operating free-air temperature range, T_A:	C suffix	0 to 70	°C
	I suffix	−40 to 125	°C
Maximum junction temperature, T_J		150	°C
Storage temperature range, T_{stg}		–65 to 150	°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds		260	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltage values, except differential voltages, are with respect to GND .

DISSIPATION RATING TABLE

PACKAGE	θ_{JC} (°C/W)	θ_{JA} (°C/W)	$T_A \leq 25°C$ POWER RATING
D (8)	38.3	176	710 mW
D (14)	26.9	122.3	1022 mW
D (16)	25.7	114.7	1090 mW
DGN (8)	4.7	52.7	2.37 W
DGQ (10)	4.7	52.3	2.39 W
N (14, 16)	32	78	1600 mW
P (8)	41	104	1200 mW
PWP (20)	1.40	26.1	4.79 W

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
Supply voltage, V_{DD}	Single supply	4.5	16	V
	Split supply	±2.25	±8	
Common-mode input voltage, V_{ICR}		GND	V_{DD}–2	V
Shutdown on/off voltage level[1]	V_{IH}	2		V
	V_{IL}		0.8	
Operating free-air temperature, T_A	C-suffix	0	70	°C
	I-suffix	−40	125	

(1) Relative to the voltage on the GND terminal of the device.

Product Folder Link(s): *TLC080 TLC081 TLC082 TLC083 TLC084 TLC085 TLC08xA*

ELECTRICAL CHARACTERISTICS

at specified free-air temperature, V_{DD} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		TA[1]	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	V_{DD} = 5 V, V_{IC} = 2.5 V, V_O = 2.5 V, R_S = 50 Ω	TLC080/1/2/3, TLC084/5	25°C		390	1900	µV
				Full range			3000	
			TLC080/1/2/3A, TLC084/5A	25°C		390	1400	
				Full range			2000	
$\propto V_{IO}$	Temperature coefficient of input offset voltage					1.2		µV/°C
I_{IO}	Input offset current	V_{DD} = 5 V, V_{IC} = 2.5 V, V_O = 2.5 V, R_S = 50 Ω		25°C		1.9	50	pA
			TLC08XC	Full range			100	
			TLC08XI				700	
I_{IB}	Input bias current			25°C		3	50	pA
			TLC08XC	Full range			100	
			TLC08XI				700	
V_{ICR}	Common-mode input voltage	R_S = 50 Ω		25°C	0 to 3.0	0 to 3.5		V
				Full range	0 to 3.0	0 to 3.5		
V_{OH}	High-level output voltage	V_{IC} = 2.5 V	I_{OH} = −1 mA	25°C	4.1	4.3		V
				Full range	3.9			
			I_{OH} = −20 mA	25°C	3.7	4		
				Full range	3.5			
			I_{OH} = −35 mA	25°C	3.4	3.8		
				Full range	3.2			
			I_{OH} = −50 mA	25°C	3.2	3.6		
				−40°C to 85°C	3			
V_{OL}	Low-level output voltage	V_{IC} = 2.5 V	I_{OL} = 1 mA	25°C		0.18	0.25	V
				Full range			0.35	
			I_{OL} = 20 mA	25°C		0.35	0.39	
				Full range			0.45	
			I_{OL} = 35 mA	25°C		0.43	0.55	
				Full range			0.7	
			I_{OL} = 50 mA	25°C		0.45	0.63	
				−40°C to 85°C			0.7	
I_{OS}	Short-circuit output current	Sourcing		25°C		100		mA
		Sinking		25°C		100		
I_O	Output current	V_{OH} = 1.5 V from positive rail		25°C		57		mA
		V_{OL} = 0.5 V from negative rail		25°C		55		
A_{VD}	Large-signal differential voltage amplification	$V_{O(PP)}$ = 3 V,	R_L = 10 kΩ	25°C	100	120		dB
				Full range	100			
$r_{i(d)}$	Differential input resistance			25°C		1000		GΩ
C_{IC}	Common-mode input capacitance	f = 10 kHz		25°C		22.9		pF
z_o	Closed-loop output impedance	f = 10 kHz,	A_V = 10	25°C		0.25		Ω
CMRR	Common-mode rejection ratio	V_{IC} = 0 to 3 V,	R_S = 50 Ω	25°C	80	110		dB
				Full range	80			
k_{SVR}	Supply voltage rejection ratio (ΔV_{DD} /ΔV_{IO})	V_{DD} = 4.5 V to 16 V,	V_{IC} = V_{DD}/2,	25°C	80	100		dB
		No load		Full range	80			

(1) Full range is 0°C to 70°C for C suffix and −40°C to 125°C for I suffix. If not specified, full range is −40°C to 125°C.

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ELECTRICAL CHARACTERISTICS (continued)

at specified free-air temperature, V_{DD} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		TA[1]	MIN	TYP	MAX	UNIT
I_{DD}	Supply current (per channel)	V_O = 2.5 V,	No load	25°C		1.8	2.5	mA
				Full range			3.5	
$I_{DD(SHDN)}$	Supply current in shutdown mode (per channel) (TLC080, TLC083, TLC085)	$\overline{SHDN}$ ≤ 0.8 V		25°C		125	200	µA
				Full range			250	

OPERATING CHARACTERISTICS

at specified free-air temperature, V_{DD} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A[1]	MIN	TYP	MAX	UNIT
SR+	Positive slew rate at unity gain	$V_{O(PP)}$ = 0.8 V, C_L = 50 pF,		25°C	10	16		V/µs
		R_L = 10 kΩ		Full range	9.5			
SR–	Negative slew rate at unity gain	$V_{O(PP)}$ = 0.8 V, C_L = 50 pF,		25°C	12.5	19		V/µs
		R_L = 10 kΩ		Full range	10			
V_n	Equivalent input noise voltage	f = 100 Hz		25°C		12		nV/√Hz
		f = 1 kHz		25°C		8.5		
I_n	Equivalent input noise current	f = 1 kHz		25°C		0.6		fA /√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 3 V,	A_V = 1	25°C		0.002		%
		R_L = 10 kΩ and 250 Ω,	A_V = 10			0.012		
		f = 1 kHz	A_V = 100			0.085		
$t_{(on)}$	Amplifier turnon time [2]	R_L = 10 kΩ		25°C		0.15		µs
$t_{(off)}$	Amplifier turnoff time [2]			25°C		1.3		µs
	Gain-bandwidth product	f = 10 kHz,	R_L = 10 kΩ	25°C		10		MHz
t_s	Settling time	$V_{(STEP)PP}$ = 1 V, A_V = −1, C_L = 10 pF, R_L = 10 kΩ	0.1%	25°C		0.18		µs
			0.01%			0.39		
		$V_{(STEP)PP}$ = 1 V, A_V = −1, C_L = 47 pF, R_L = 10 kΩ	0.1%			0.18		
			0.01%			0.39		
φ_m	Phase margin	R_L = 10 kΩ,	C_L = 50 pF	25°C		32		°
		R_L = 10 kΩ,	C_L = 0 pF			40		
	Gain margin	R_L = 10 kΩ,	C_L = 50 pF	25°C		2.2		dB
		R_L = 10 kΩ,	C_L = 0 pF			3.3		

(1) Full range is 0°C to 70°C for C suffix and –40°C to 125°C for I suffix. If not specified, full range is –40°C to 125°C.
(2) Disable time and enable time are defined as the interval between application of the logic signal to SHDN and the point at which the supply current has reached half its final value.

Product Folder Link(s): *TLC080 TLC081 TLC082 TLC083 TLC084 TLC085 TLC08xA*

ELECTRICAL CHARACTERISTICS

at specified free-air temperature, V_{DD} = 12 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		TA[1]	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	V_{DD} = 12 V, V_{IC} = 6 V, V_O = 6 V, R_S = 50 Ω	TLC080/1/2/3, TLC084/5	25°C		390	1900	µV
				Full range			3000	
			TLC080/1/2/3A, TLC084/5A	25°C		390	1400	
				Full range			2000	
$\propto V_{IO}$	Temperature coefficient of input offset voltage					1.2		µV/°C
I_{IO}	Input offset current	V_{DD} = 12 V, V_{IC} = 6 V, V_O = 6 V, R_S = 50 Ω		25°C		1.5	50	pA
			TLC08xC	Full range			100	
			TLC08xI				700	
I_{IB}	Input bias current			25°C		3	50	pA
			TLC08xC	Full range			100	
			TLC08xI				700	
V_{ICR}	Common-mode input voltage	R_S = 50 Ω		25°C	0 to 10.0	0 to 10.5		V
				Full range	0 to 10.0	0 to 10.5		
V_{OH}	High-level output voltage	V_{IC} = 6 V	I_{OH} = −1 mA	25°C	11.1	11.2		V
				Full range	11			
			I_{OH} = −20 mA	25°C	10.8	11		
				Full range	10.7			
			I_{OH} = −35 mA	25°C	10.6	10.7		
				Full range	10.3			
			I_{OH} = −50 mA	25°C	10.3	10.5		
				−40°C to 85°C	10.2			
V_{OL}	Low-level output voltage	V_{IC} = 6 V	I_{OL} = 1 mA	25°C		0.17	0.25	V
				Full range			0.35	
			I_{OL} = 20 mA	25°C		0.35	0.45	
				Full range			0.5	
			I_{OL} = 35 mA	25°C		0.4	0.52	
				Full range			0.6	
			I_{OL} = 50 mA	25°C		0.45	0.6	
				−40°C to 85°C			0.65	
I_{OS}	Short-circuit output current	Sourcing		25°C		150		mA
		Sinking		25°C		150		
I_O	Output current	V_{OH} = 1.5 V from positive rail		25°C		57		mA
		V_{OL} = 0.5 V from negative rail		25°C		55		
A_{VD}	Large-signal differential voltage amplification	$V_{O(PP)}$ = 8 V, R_L = 10 kΩ		25°C	120	140		dB
				Full range	120			
$r_{i(d)}$	Differential input resistance			25°C		1000		GΩ
C_{IC}	Common-mode input capacitance	f = 10 kHz		25°C		21.6		pF
z_o	Closed-loop output impedance	f = 10 kHz, A_V = 10		25°C		0.25		Ω
CMRR	Common-mode rejection ratio	V_{IC} = 0 to 10 V, R_S = 50 Ω		25°C	80	110		dB
				Full range	80			
k_{SVR}	Supply voltage rejection ratio ($\Delta V_{DD} /\Delta V_{IO}$)	V_{DD} = 4.5 V to 16 V, V_{IC} = V_{DD}/2, No load		25°C	80	100		dB
				Full range	80			

(1) Full range is 0°C to 70°C for C suffix and −40°C to 125°C for I suffix. If not specified, full range is −40°C to 125°C.

ELECTRICAL CHARACTERISTICS (continued)

at specified free-air temperature, V_{DD} = 12 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		TA[1]	MIN	TYP	MAX	UNIT
I_{DD}	Supply current (per channel)	V_O = 7.5 V,	No load	25°C		1.9	2.9	mA
				Full range			3.5	
$I_{DD(SHDN)}$	Supply current in shutdown mode (TLC080, TLC083, TLC085) (per channel)	$\overline{SHDN}$ ≤ 0.8 V		25°C		125	200	µA
				Full range			250	

OPERATING CHARACTERISTICS

at specified free-air temperature, V_{DD} = 12 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A[1]	MIN	TYP	MAX	UNIT
SR+	Positive slew rate at unity gain	$V_{O(PP)}$ = 2 V, C_L = 50 pF,		25°C	10	16		V/µs
		R_L = 10 kΩ		Full range	9.5			
SR–	Negative slew rate at unity gain	$V_{O(PP)}$ = 2 V, C_L = 50 pF,		25°C	12.5	19		V/µs
		R_L = 10 kΩ		Full range	10			
V_n	Equivalent input noise voltage	f = 100 Hz		25°C		14		nV/√Hz
		f = 1 kHz		25°C		8.5		
I_n	Equivalent input noise current	f = 1 kHz		25°C		0.6		fA /√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 8 V, R_L = 10 kΩ and 250 Ω, f = 1 kHz	A_V = 1	25°C		0.002		%
			A_V = 10			0.005		
			A_V = 100			0.022		
$t_{(on)}$	Amplifier turnon time[2]	R_L = 10 kΩ		25°C		0.47		µs
$t_{(off)}$	Amplifier turnoff time[2]			25°C		2.5		µs
	Gain-bandwidth product	f = 10 kHz,	R_L = 10 kΩ	25°C		10		MHz
t_s	Settling time	$V_{(STEP)PP}$ = 1 V, A_V = −1, C_L = 10 pF, R_L = 10 kΩ	0.1%	25°C		0.17		µs
			0.01%			0.22		
		$V_{(STEP)PP}$ = 1 V, A_V = −1, C_L = 47 pF, R_L = 10 kΩ	0.1%			0.17		
			0.01%			0.29		
φ_m	Phase margin	R_L = 10 kΩ,	C_L = 50 pF	25°C		37		°
		R_L = 10 kΩ,	C_L = 0 pF			42		
	Gain margin	R_L = 10 kΩ,	C_L = 50 pF	25°C		3.1		dB
		R_L = 10 kΩ,	C_L = 0 pF			4		

(1) Full range is 0°C to 70°C for C suffix and –40°C to 125°C for I suffix. If not specified, full range is –40°C to 125°C.
(2) Disable time and enable time are defined as the interval between application of the logic signal to SHDN and the point at which the supply current has reached half its final value.

Product Folder Link(s): *TLC080 TLC081 TLC082 TLC083 TLC084 TLC085 TLC08xA*

TYPICAL CHARACTERISTICS

Table of Graphs

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V_{OL}	Low-level output voltage	vs Low-level output current	6, 8
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PSRR	Power supply rejection ratio	vs Frequency	11
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TYPICAL CHARACTERISTICS

INPUT OFFSET VOLTAGE
vs
COMMON-MODE INPUT VOLTAGE
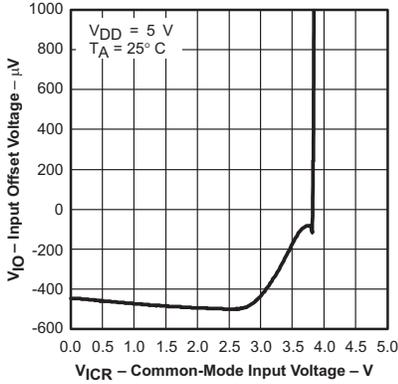
INPUT OFFSET VOLTAGE
vs
COMMON-MODE INPUT VOLTAGE
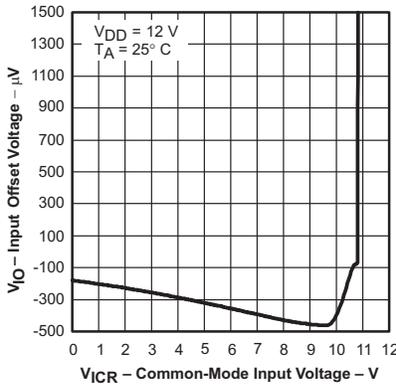
INPUT BIAS CURRENT AND
INPUT OFFSET CURRENT
vs
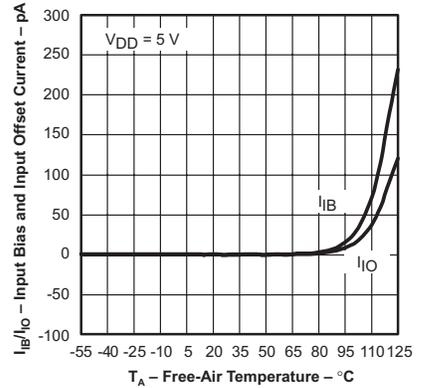**FREE-AIR TEMPERATURE**

Figure 1.

Figure 2.

Figure 3.

INPUT BIAS CURRENT AND
INPUT OFFSET CURRENT
vs
FREE-AIR TEMPERATURE

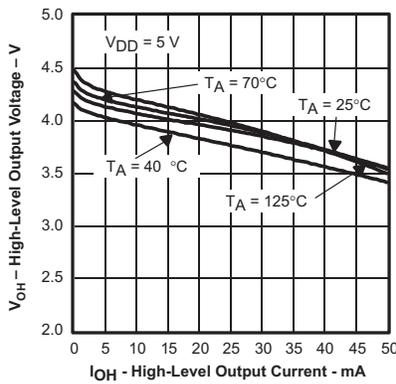**HIGH-LEVEL OUTPUT VOLTAGE**
vs
HIGH-LEVEL OUTPUT CURRENT
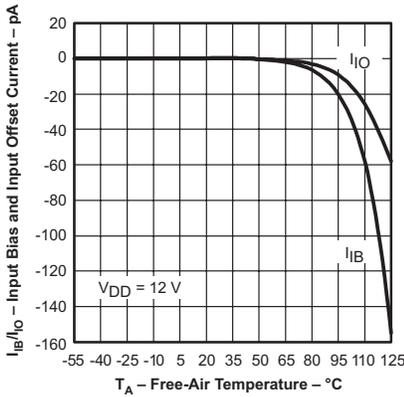
LOW-LEVEL OUTPUT VOLTAGE
vs
LOW-LEVEL OUTPUT CURRENT

Figure 4.
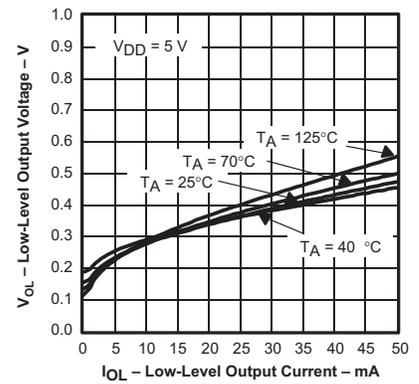
Figure 5.

Figure 6.

HIGH-LEVEL OUTPUT VOLTAGE
vs
HIGH-LEVEL OUTPUT CURRENT

LOW-LEVEL OUTPUT VOLTAGE
vs
LOW-LEVEL OUTPUT CURRENT

OUTPUT IMPEDANCE
vs
FREQUENCY

Figure 7.

Figure 8.

Figure 9.

Product Folder Link(s): *TLC080 TLC081 TLC082 TLC083 TLC084 TLC085 TLC08xA*
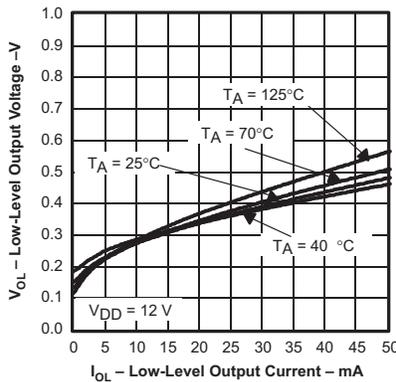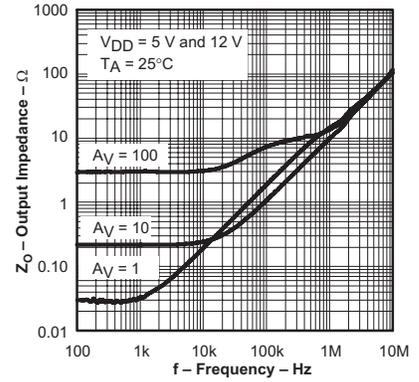
TYPICAL CHARACTERISTICS

SUPPLY CURRENT
vs
SUPPLY VOLTAGE
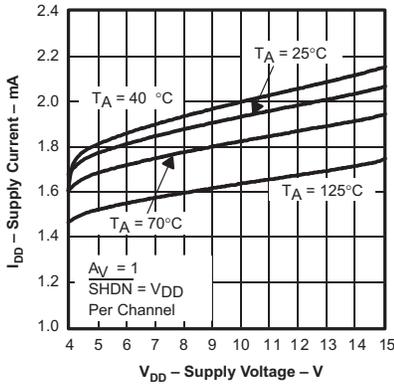
Figure 10.

POWER SUPPLY REJECTION
RATIO
vs
FREQUENCY
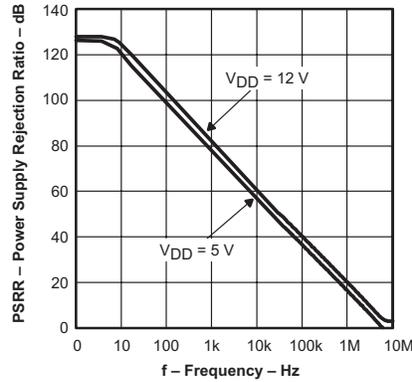
Figure 11.

COMMON-MODE REJECTION RATIO
vs
FREQUENCY
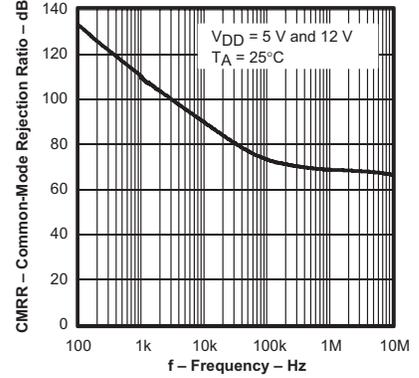
Figure 12.

EQUIVALENT INPUT NOISE
VOLTAGE
vs
FREQUENCY
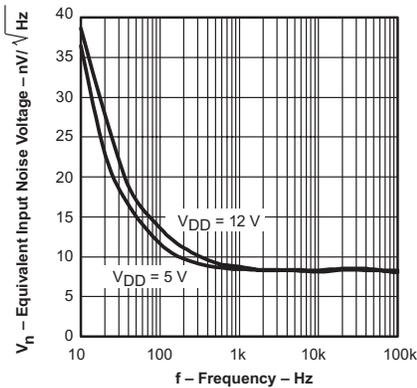
Figure 13.

PEAK-TO-PEAK OUTPUT
VOLTAGE
vs
FREQUENCY
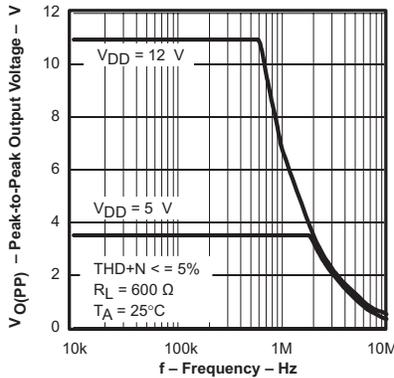
Figure 14.

PEAK-TO-PEAK OUTPUT
VOLTAGE
vs
FREQUENCY
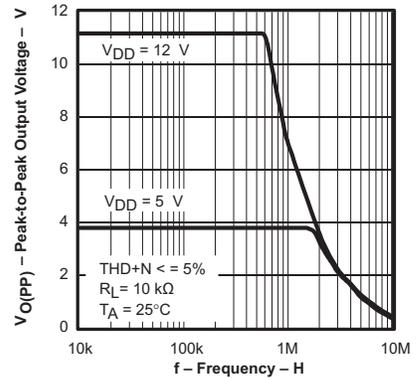
Figure 15.

CROSSTALK
vs
FREQUENCY

Figure 16.

Product Folder Link(s): *TLC080 TLC081 TLC082 TLC083 TLC084 TLC085 TLC08xA*
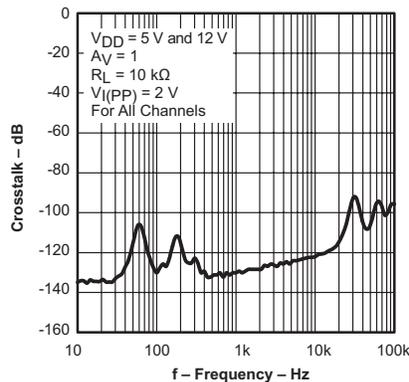
TYPICAL CHARACTERISTICS

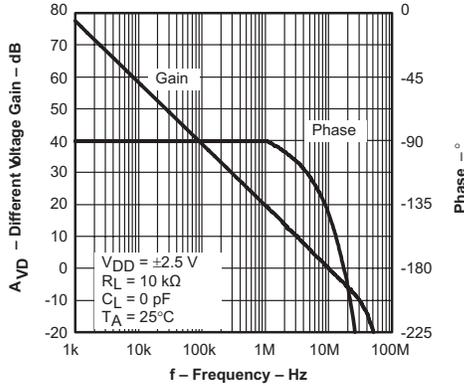DIFFERENTIAL VOLTAGE GAIN AND
PHASE
vs
FREQUENCY

Figure 17.

DIFFERENTIAL VOLTAGE GAIN AND
PHASE
vs
FREQUENCY

Figure 18.
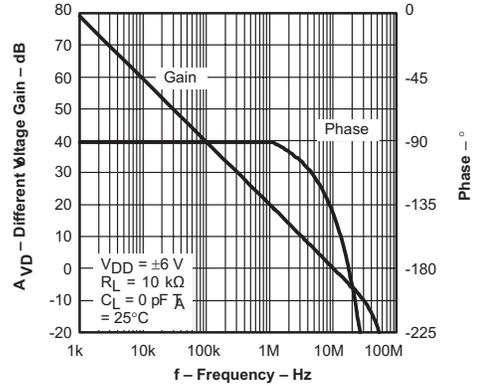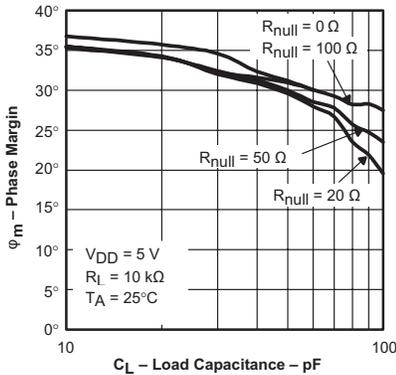
PHASE MARGIN
vs
LOAD CAPACITANCE

Figure 19.
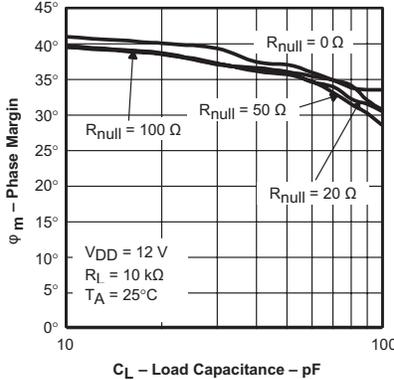
PHASE MARGIN
vs
LOAD CAPACITANCE

Figure 20.

GAIN MARGIN
vs
LOAD CAPACITANCE
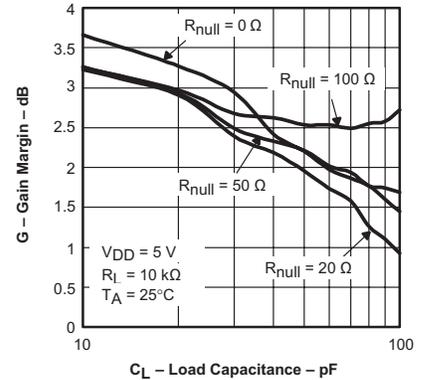
Figure 21.

GAIN MARGIN
vs
LOAD CAPACITANCE
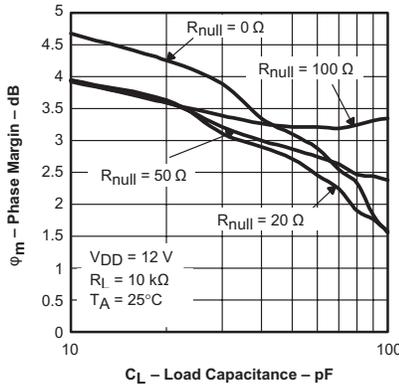
Figure 22.

GAIN BANDWIDTH PRODUCT
vs
SUPPLY VOLTAGE
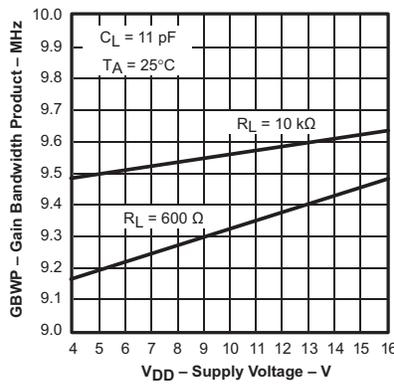
Figure 23.

SLEW RATE
vs
SUPPLY VOLTAGE

Figure 24.

Product Folder Link(s): *TLC080 TLC081 TLC082 TLC083 TLC084 TLC085 TLC08xA*

TYPICAL CHARACTERISTICS

SLEW RATE
vs
FREE-AIR TEMPERATURE

Figure 25.

SLEW RATE
vs
FREE-AIR TEMPERATURE

Figure 26.

TOTAL HARMONIC DISTORTION
PLUS NOISE
vs
FREQUENCY

Figure 27.

TOTAL HARMONIC DISTORTION
PLUS NOISE
vs
FREQUENCY

Figure 28.

TOTAL HARMONIC DISTORTION
PLUS NOISE
vs
PEAK-TO-PEAK OUTPUT VOLTAGE

Figure 29.

TOTAL HARMONIC DISTORTION
PLUS NOISE
vs
PEAK-TO-PEAK OUTPUT VOLTAGE

Figure 30.

LARGE SIGNAL FOLLOWER
PULSE RESPONSE

Figure 31.

LARGE SIGNAL FOLLOWER
PULSE RESPONSE

Figure 32.

SMALL SIGNAL FOLLOWER
PULSE RESPONSE

Figure 33.

Product Folder Link(s): TLC080 TLC081 TLC082 TLC083 TLC084 TLC085 TLC08xA

TYPICAL CHARACTERISTICS

LARGE SIGNAL INVERTING
PULSE RESPONSE
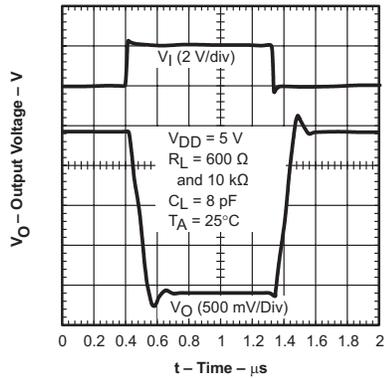
Figure 34.

LARGE SIGNAL INVERTING
PULSE RESPONSE
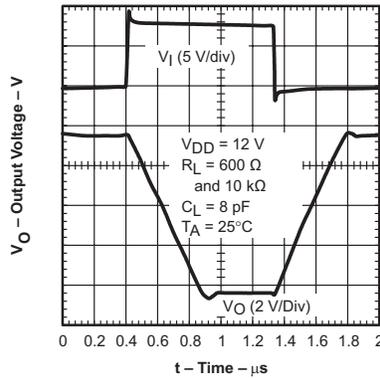
Figure 35.

SMALL SIGNAL INVERTING
PULSE RESPONSE
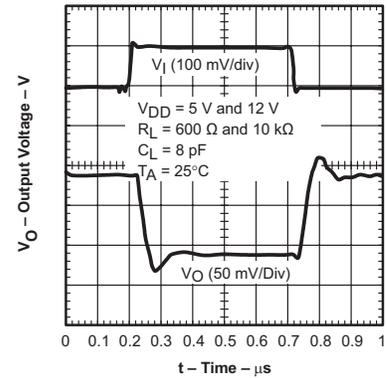
Figure 36.

SHUTDOWN FORWARD
ISOLATION
vs
FREQUENCY
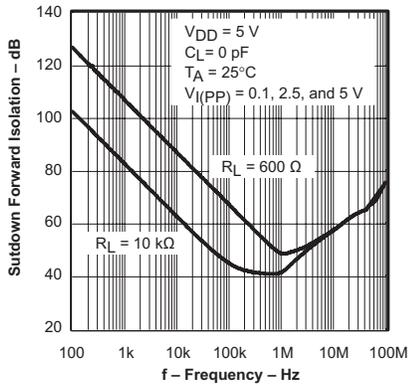
Figure 37.

SHUTDOWN FORWARD
ISOLATION
vs
FREQUENCY
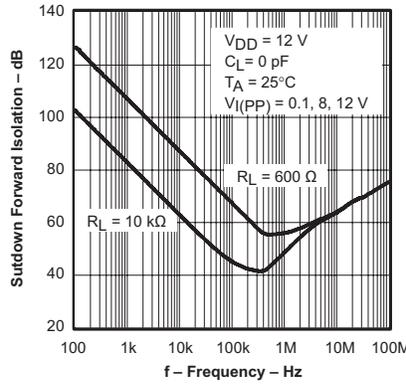
Figure 38.

SHUTDOWN REVERSE
ISOLATION
vs
FREQUENCY
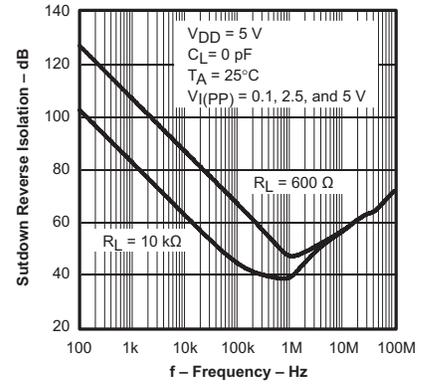
Figure 39.

SHUTDOWN REVERSE
ISOLATION
vs
FREQUENCY
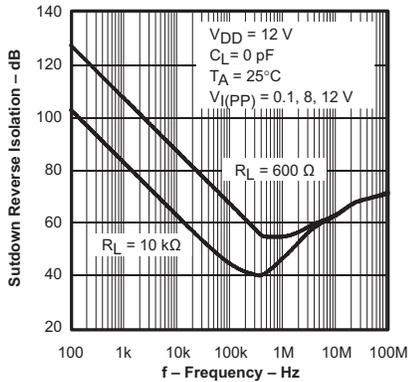
Figure 40.

SHUTDOWN SUPPLY CURRENT
vs
SUPPLY VOLTAGE
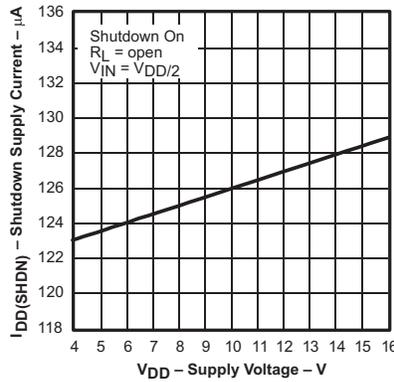
Figure 41.

SHUTDOWN SUPPLY CURRENT
vs
FREE-AIR TEMPERATURE

Figure 42.

Product Folder Link(s): *TLC080 TLC081 TLC082 TLC083 TLC084 TLC085 TLC08xA*

TYPICAL CHARACTERISTICS

SHUTDOWN PULSE

Figure 43.

SHUTDOWN PULSE
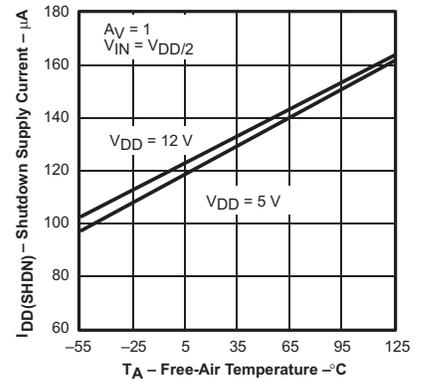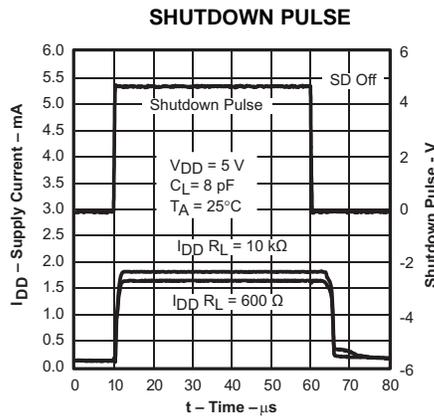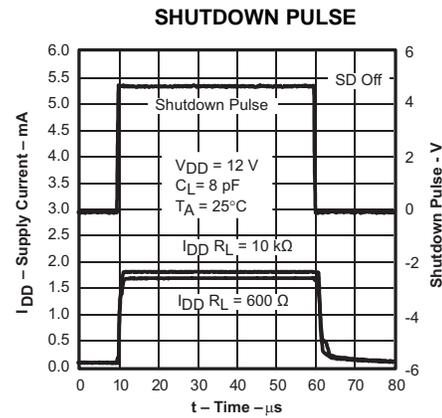
Figure 44.

PARAMETER MEASUREMENT INFORMATION
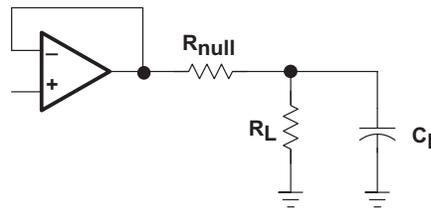
Figure 45

Figure 45.

APPLICATION INFORMATION

Input Offset Voltage Null Circuit

The TLC080 and TLC081 has an input offset nulling function. Refer to Figure 46 for the diagram.
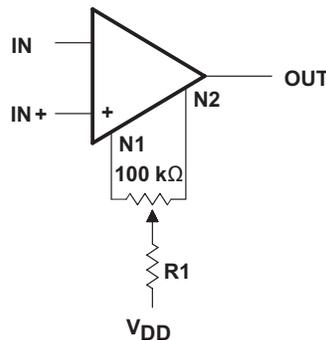
A.   R1 = 5.6 kΩ for offset voltage adjustment of ±10 mV. R1 = 20 kΩ for offset voltage adjustment of ±3 mV.

Figure 46. Input Offset Voltage Null Circuit

TLC080 , TLC081, TLC082
TLC083, TLC084, TLC085, TLC08xA

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Driving a Capacitive Load

When the amplifier is configured in this manner, capacitive loading directly on the output will decrease the device's phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series (R_{NULL}) with the output of the amplifier, as shown in Figure 47. A minimum value of 20 Ω should work well for most applications.
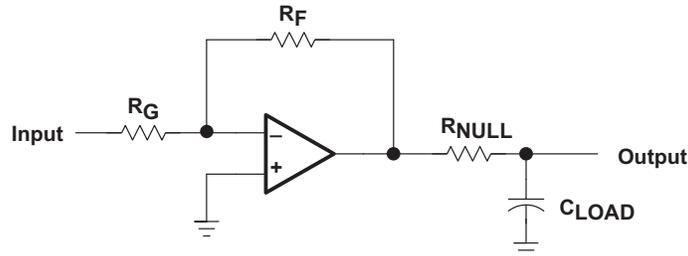
Figure 47. Driving a Capacitive Load

Offset Voltage

The output offset voltage, (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:

$$V_{OO} = V_{IO}\left(1 + \left(\frac{R_F}{R_G}\right)\right) \pm I_{IB} + R_S \left(1 + \left(\frac{R_F}{R_G}\right)\right) \pm I_{IB-}\, R_F$$
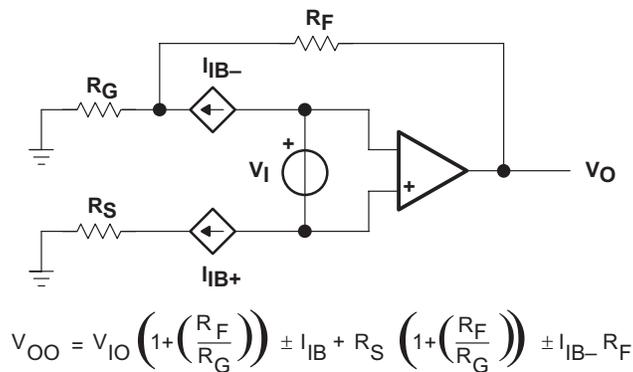
Figure 48. Output Offset Voltage Model

High Speed CMOS Input Amplifiers

The TLC08x is a family of high-speed low-noise CMOS input operational amplifiers that has an input capacitance of the order of 20 pF. Any resistor used in the feedback path adds a pole in the transfer function equivalent to the input capacitance multiplied by the combination of source resistance and feedback resistance. For example, a gain of −10, a source resistance of 1 kΩ, and a feedback resistance of 10 kΩ add an additional pole at approximately 8 MHz. This is more apparent with CMOS amplifiers than bipolar amplifiers due to their greater input capacitance.

This is of little consequence on slower CMOS amplifiers, as this pole normally occurs at frequencies above their unity-gain bandwidth. However, the TLC08x with its 10-MHz bandwidth means that this pole normally occurs at frequencies where there is on the order of 5dB gain left and the phase shift adds considerably.

The effect of this pole is the strongest with large feedback resistances at small closed loop gains. As the feedback resistance is increased, the gain peaking increases at a lower frequency and the 180° phase shift crossover point also moves down in frequency, decreasing the phase margin.

For the TLC08x, the maximum feedback resistor recommended is 5 kΩ; larger resistances can be used but a capacitor in parallel with the feedback resistor is recommended to counter the effects of the input capacitance pole.

The TLC083 with a 1-V step response has an 80% overshoot with a natural frequency of 3.5 MHz when configured as a unity gain buffer and with a 10-kΩ feedback resistor. By adding a 10-pF capacitor in parallel with the feedback resistor, the overshoot is reduced to 40% and eliminates the natural frequency, resulting in a much faster settling time (see Figure 49). The 10-pF capacitor was chosen for convenience only.

Load capacitance had little effect on these measurements due to the excellent output drive capability of the TLC08x.
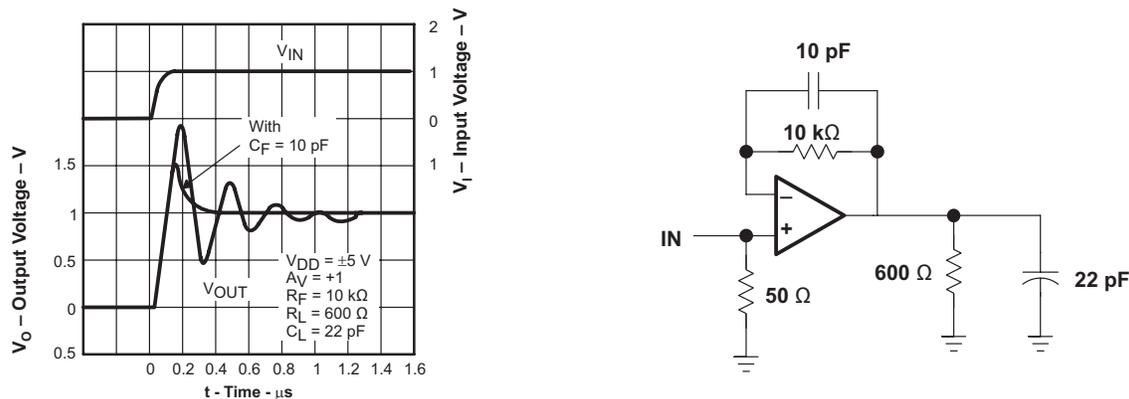
Figure 49. 1-V Step Response

TLC080 , TLC081, TLC082
TLC083, TLC084, TLC085, TLC08xA

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General Configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the Figure 50 system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see).

$$f_{-3dB} = \frac{1}{2\pi R1 C1}$$

$$\frac{V_O}{V_I} = \left(1 + \frac{R_F}{R_G}\right)\left(\frac{1}{1 + sR1C1}\right)$$
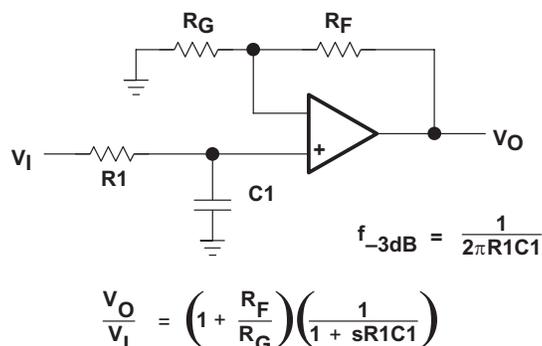
Figure 50. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.

R1 = R2 = R
C1 = C2 = C
Q = Peaking Factor
(Butterworth Q = 0.707)

$$f_{-3dB} = \frac{1}{2\pi RC}$$

$$R_G = \frac{R_F}{\left(2 - \frac{1}{Q}\right)}$$
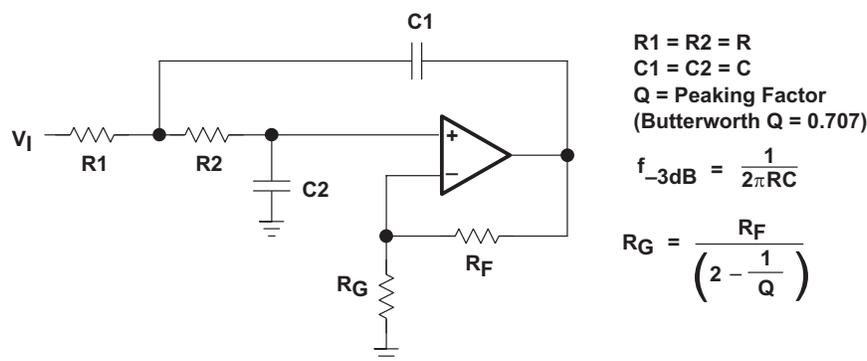
Figure 51. 2-Pole Low-Pass Sallen-Key Filter

Product Folder Link(s): *TLC080 TLC081 TLC082 TLC083 TLC084 TLC085 TLC08xA*

Shutdown Function

Three members of the TLC08x family (TLC080/3/5) have a shutdown terminal (SHDN) for conserving battery life in portable applications. When the shutdown terminal is tied low, the supply current is reduced to 125 µA/channel, the amplifier is disabled, and the outputs are placed in a high-impedance mode. To enable the amplifier, the shutdown terminal can either be left floating or pulled high. When the shutdown terminal is left floating, care should be taken to ensure that parasitic leakage current at the shutdown terminal does not inadvertently place the operational amplifier into shutdown. The shutdown terminal threshold is always referenced to the voltage on the GND terminal of the device. Therefore, when operating the device with split supply voltages (e.g. ±2.5 V), the shutdown terminal needs to be pulled to V_{DD-} (not system ground) to disable the operational amplifier.

The amplifier's output with a shutdown pulse is shown in Figure 43 and Figure 44. The amplifier is powered with a single 5-V supply and is configured as noninverting with a gain of 5. The amplifier turnon and turnoff times are measured from the 50% point of the shutdown pulse to the 50% point of the output waveform. The times for the single, dual, and quad are listed in the data tables.

Figure 37 through Figure 40 show the amplifiers forward and reverse isolation in shutdown. The operational amplifier is configured as a voltage follower ($A_V = 1$). The isolation performance is plotted across frequency using 0.1 V_{PP}, 2.5 V_{PP}, and 5 V_{PP} input signals at ±2.5 V supplies and 0.1 V_{PP}, 8 V_{PP}, and 12 V_{PP} input signals at ±6 V supplies.

Circuit Layout Considerations

To achieve the levels of high performance of the TLC08x, follow proper printed-circuit board design techniques. A general set of guidelines is given in the following.

- Ground planes – It is highly recommended that a ground plane be used on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling – Use a 6.8-µF tantalum capacitor in parallel with a 0.1-µF ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1-µF ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1-µF capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets – Sockets can be used but are not recommended. The additional lead inductance in the socket pins will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- Short trace runs/compact part placements – Optimum high performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This will help to minimize stray capacitance at the input of the amplifier.
- Surface-mount passive components – Using surface-mount passive components is recommended for high performance amplifier circuits for several reasons. First, because of the extremely low lead inductance of surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small size of surface-mount components naturally leads to a more compact layout thereby minimizing both stray inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be kept as short as possible.

General PowerPAD Design Considerations

The TLC08x is available in a thermally-enhanced PowerPAD family of packages. These packages are constructed using a downset leadframe upon which the die is mounted [see Figure 52(a) and Figure 52(b)]. This arrangement results in the lead frame being exposed as a thermal pad on the underside of the package [see Figure 52(c)]. Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad.

Side View (a)

End View (b)

Bottom View (c)
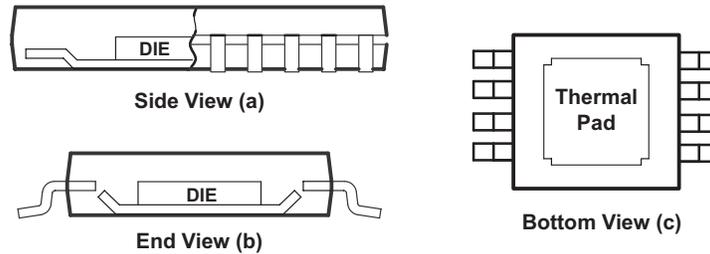
A.   The thermal pad is electrically isolated from all terminals in the package.

Figure 52. Views of Thermally-Enhanced DGN Package

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad must be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat dissipating device. **Soldering the PowerPAD to the printed circuit board (PCB) is always required, even with applications that have low power dissipation.** This soldering provides the necessary thermal and mechanical connection between the lead frame die pad and the PCB.

Although there are many ways to properly heatsink the PowerPAD package, the following steps illustrate the recommended approach.

The PowerPAD must be connected to the most negative supply voltage (GND pin potential) of the device.

1. Prepare the PCB with a top side etch pattern (see the landing patterns at the end of this data sheet). There should be etch for the leads as well as etch for the thermal pad.

2. Place five holes (dual) or nine holes (quad) in the area of the thermal pad. These holes should be 13 mils in diameter. Keep them small so that solder wicking through the holes is not a problem during reflow.

3. Additional vias may be placed anywhere along the thermal plane outside of the thermal pad area. This helps dissipate the heat generated by the TLC08x IC. These additional vias may be larger than the 13-mil diameter vias directly under the thermal pad. They can be larger because they are not in the thermal pad area to be soldered so that wicking is not a problem.

4. Connect all holes to the internal plane that is at the same potential as the ground pin of the device.

5. When connecting these holes to this internal plane, do not use the typical web or spoke via connection methodology. Web connections have a high thermal resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the TLC08x PowerPAD package should make their connection to the internal ground plane with a complete connection around the entire circumference of the plated-through hole.

6. The top-side solder mask should leave the terminals of the package and the thermal pad area with its five holes (dual) or nine holes (quad) exposed. The bottom-side solder mask should cover the five or nine holes of the thermal pad area. This prevents solder from being pulled away from the thermal pad area during the reflow process.

7. Apply solder paste to the exposed thermal pad area and all of the IC terminals.

8. With these preparatory steps in place, the TLC08x IC is simply placed in position and run through the solder reflow operation as any standard surface-mount component. This results in a part that is properly installed.

For a given θ_{JA}, the maximum power dissipation is shown in Figure 53 and is calculated by the following formula:

$$P_D = \left(\frac{T_{MAX} - T_A}{\theta_{JA}} \right)$$

(1)

Where:

P_D =   Maximum power dissipation of TLC08x IC (watts)

T_{MAX} =   Absolute maximum junction temperature (150°C)

T_A =   Free-ambient air temperature (°C)

θ_{JA} = $\theta_{JC} + \theta_{CA}$

              θ_{JC} = Thermal coefficient from junction to case

              θ_{CA} = Thermal coefficient from case to ambient air (°C/W)
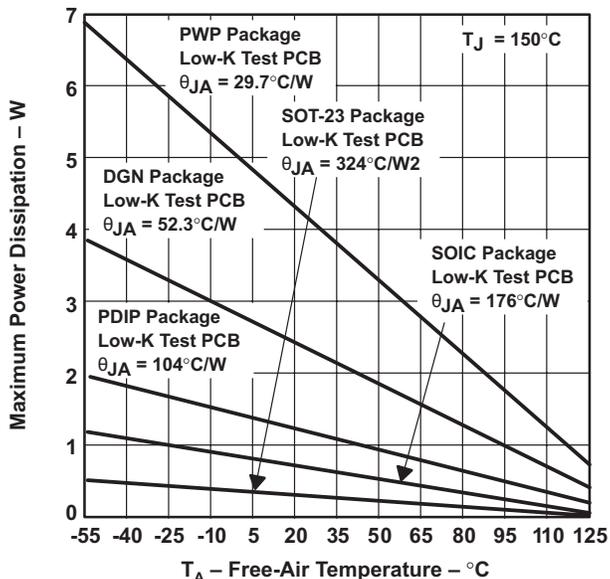
A.   Results are with no air flow and using JEDEC Standard Low-K test PCB.

Figure 53. Maximum Power Dissipation vs Free-Air Temperature

The next consideration is the package constraints. The two sources of heat within an amplifier are quiescent power and output power. The designer should never forget about the quiescent heat generated within the device, especially multi-amplifier devices. Because these devices have linear output stages (Class A-B), most of the heat dissipation is at low output voltages with high output currents.

The other key factor when dealing with power dissipation is how the devices are mounted on the PCB. The PowerPAD devices are extremely useful for heat dissipation. But, the device should always be soldered to a copper plane to fully use the heat dissipation properties of the PowerPAD. The SOIC package, on the other hand, is highly dependent on how it is mounted on the PCB. As more trace and copper area is placed around the device, θ_{JA} decreases and the heat dissipation capability increases. The currents and voltages shown in these graphs are for the total package. For the dual or quad amplifier packages, the sum of the RMS output currents and voltages should be used to choose the proper package.

Macromodel Information

Macromodel information provided was derived using Microsim Parts™, the model generation software used with Microsim PSpice™. The Boyle macromodel (see [1]) and subcircuit in Figure 54 are generated using the TLC08x typical electrical and operating characteristics at T_A = 25°C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

(1)   G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers," IEEE Journal of Solid-State Circuits, SC-9, 353 (1974).

(schematic diagram)
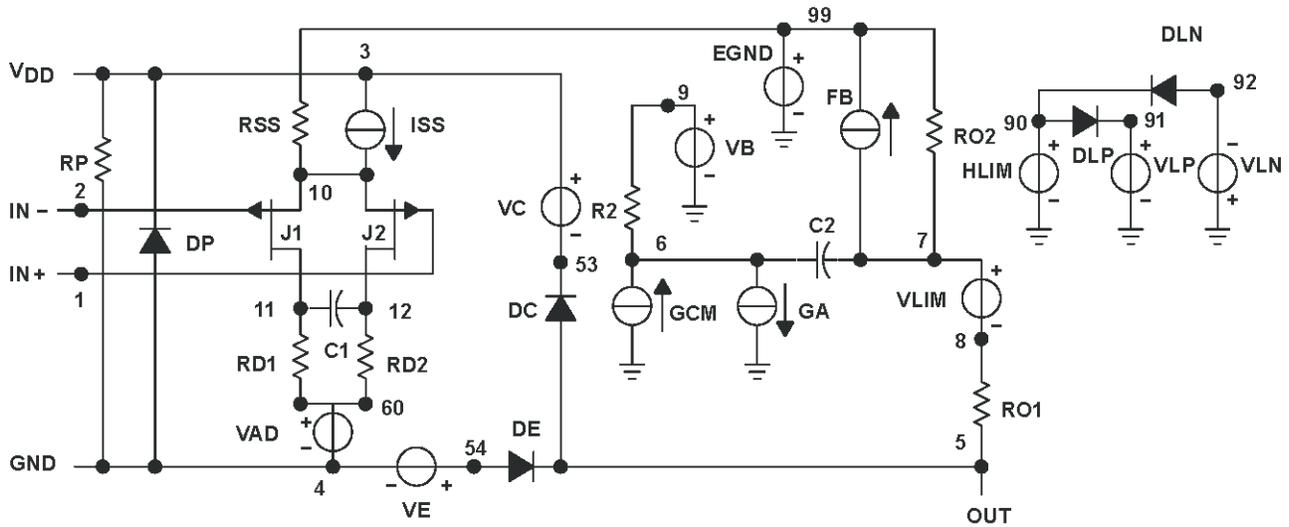
```
*DEVICE=TLC08X_5V, OPAMP, PJF, INT

* TLC08X_5V − 5V operational amplifier "macromodel" sub-
circuit
* created using Parts release 8.0 on 12/16/99 at 14:03
* Parts is a MicroSim product.
*
* connections:    non-inverting input
*                 | inverting input
*                 | | positive power supply
*                 | | | negative power supply
*                 | | | | output
*                 | | | | |
.subckt TLC08X_5V 1 2 3 4 5
*
c1      11  12  4.6015E−12
c2      6   7   8.0000E−12
css     10  99  986.29E−15
dc      5   53  dy
de      54  5   dy
dlp     90  91  dx
dln     92  90  dx
dp      4   3   dx
egnd    99  0   poly(2) (3,0) (4,0) 0 .5 .5
fb      7   99  poly(5) vb vc ve vlp vln 0 13.984E6 −1E3 1E3
                14E6 −14E6
```

```
ga      6   0   11  12 402.12E−6
gcm     0   6   10  99 1.5735E−6
ioff    0   6   dc  1.212E−6
iss     3   10  dc  130.40E−6
hlim    90  0   vlim  1K
j1      11  2   10  jx1
j2      12  1   10  jx2
r2      6   9       100.00E3
rd1     4   11      2.4868E3
rd2     4   12      2.4868E3
ro1     8   5   10
ro2     7   99  10
rp      3   4       2.8249E3
rss     10  99      1.5337E6
vb      9   0   dc  0
vc      3   53  dc  1.5537
ve      54  4   dc  .84373
vlim    7   8   dc  0
vlp     91  0   dc  117.60
vln     0   92  dc  117.60
.model  dx  D(Is=800.00E−18)
.model  dy  D(Is=800.00E−18 Rs=1m Cjo=10p)
.model  jx1 PJF(Is=80.000E−15 Beta=1.2401E−3 Vto=−1)
.model  jx2 PJF(Is=80.000E−15 Beta=1.2401E−3 Vto=−1)
.ends
```

Figure 54. Boyle Macromodel and Subcircuit

REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision E (April 2006) to Revision F   **Page**

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLC080AIDR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C080AI
TLC080AIDR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C080AI
TLC080AIP	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLC080AI
TLC080AIP.A	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLC080AI
TLC080CDGNR	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ACW
TLC080CDGNR.A	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ACW
TLC080CDGNRG4	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	-	Call TI	Call TI	0 to 70	
TLC080CDR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	C080C
TLC080CDR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	C080C
TLC080ID	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C080I
TLC080ID.A	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C080I
TLC080IDGNR	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ACX
TLC080IDGNR.A	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ACX
TLC080IDR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C080I
TLC080IDR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C080I
TLC081AID	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C081AI
TLC081AID.A	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C081AI
TLC081AIDR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C081AI
TLC081AIDR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C081AI
TLC081AIP	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLC081AI
TLC081AIP.A	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLC081AI
TLC081CD	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	C081C
TLC081CD.A	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	C081C
TLC081CDGN	Obsolete	Production	HVSSOP (DGN) | 8	-	-	Call TI	Call TI	0 to 70	ACY
TLC081CDGNR	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ACY
TLC081CDGNR.A	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ACY
TLC081CDR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	C081C
TLC081CDR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	C081C
TLC081CP	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC081C

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLC081CP.A	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC081C
TLC081ID	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C081I
TLC081ID.A	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C081I
TLC081IDGNR	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ACZ
TLC081IDGNR.A	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ACZ
TLC081IDR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C081I
TLC081IDR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C081I
TLC081IP	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLC081I
TLC081IP.A	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLC081I
TLC082AID	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C082AI
TLC082AID.A	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C082AI
TLC082AID.B	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C082AI
TLC082AIDR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C082AI
TLC082AIDR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C082AI
TLC082AIDR.B	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C082AI
TLC082AIDRG4	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
TLC082AIP	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	C082AI
TLC082AIP.A	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	C082AI
TLC082CD	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	C082C
TLC082CD.A	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	C082C
TLC082CD.B	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	C082C
TLC082CDG4	Active	Production	SOIC (D) | 8	75 | TUBE	-	Call TI	Call TI	0 to 70	
TLC082CDGN	Active	Production	HVSSOP (DGN) | 8	80 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ADZ
TLC082CDGN.A	Active	Production	HVSSOP (DGN) | 8	80 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ADZ
TLC082CDGN.B	Active	Production	HVSSOP (DGN) | 8	80 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ADZ
TLC082CDGNR	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ADZ
TLC082CDGNR.A	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ADZ
TLC082CDGNR.B	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ADZ
TLC082CDR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	C082C
TLC082CDR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	C082C
TLC082CDR.B	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	C082C

Orderable part number (1)	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLC082CP	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	C082C
TLC082CP.A	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	C082C
TLC082CP.B	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	C082C
TLC082ID	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C082I
TLC082ID.A	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C082I
TLC082ID.B	Active	Production	SOIC (D) | 8	75 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C082I
TLC082IDGN	Active	Production	HVSSOP (DGN) | 8	80 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AEA
TLC082IDGN.A	Active	Production	HVSSOP (DGN) | 8	80 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AEA
TLC082IDGN.B	Active	Production	HVSSOP (DGN) | 8	80 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AEA
TLC082IDGNR	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AEA
TLC082IDGNR.A	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AEA
TLC082IDGNR.B	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AEA
TLC082IDR	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C082I
TLC082IDR.A	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C082I
TLC082IDR.B	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C082I
TLC082IDRG4	Active	Production	SOIC (D) | 8	2500 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
TLC082IP	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	C082I
TLC082IP.A	Active	Production	PDIP (P) | 8	50 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	C082I
TLC083AID	Active	Production	SOIC (D) | 14	50 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C083AI
TLC083AID.A	Active	Production	SOIC (D) | 14	50 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C083AI
TLC083CDGQR	Active	Production	HVSSOP (DGQ) | 10	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	AEB
TLC083CDGQR.A	Active	Production	HVSSOP (DGQ) | 10	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	AEB
TLC083CDGQR.B	Active	Production	HVSSOP (DGQ) | 10	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	AEB
TLC083CDR	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	C083C
TLC083CDR.A	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	C083C
TLC083CDR.B	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	C083C
TLC083CN	Active	Production	PDIP (N) | 14	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	C083C
TLC083CN.A	Active	Production	PDIP (N) | 14	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	C083C
TLC083IDGQ	Active	Production	HVSSOP (DGQ) | 10	80 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AEC
TLC083IDGQ.A	Active	Production	HVSSOP (DGQ) | 10	80 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AEC
TLC083IDGQ.B	Active	Production	HVSSOP (DGQ) | 10	80 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AEC

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLC083IN	Active	Production	PDIP (N) | 14	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	C083I
TLC083IN.A	Active	Production	PDIP (N) | 14	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	C083I
TLC084AID	Active	Production	SOIC (D) | 14	50 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLC084AI
TLC084AID.B	Active	Production	SOIC (D) | 14	50 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLC084AI
TLC084AIDG4	Active	Production	SOIC (D) | 14	50 | TUBE	-	Call TI	Call TI	-40 to 125	
TLC084AIDR	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLC084AI
TLC084AIDR.A	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLC084AI
TLC084AIDR.B	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLC084AI
TLC084AIDRG4	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLC084AI
TLC084AIDRG4.A	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLC084AI
TLC084AIDRG4.B	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLC084AI
TLC084AIN	Active	Production	PDIP (N) | 14	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLC084AI
TLC084AIN.B	Active	Production	PDIP (N) | 14	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLC084AI
TLC084AIPWP	Active	Production	HTSSOP (PWP) | 20	70 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TLC084AI
TLC084AIPWP.B	Active	Production	HTSSOP (PWP) | 20	70 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TLC084AI
TLC084AIPWPR	Active	Production	HTSSOP (PWP) | 20	2000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TLC084AI
TLC084AIPWPR.B	Active	Production	HTSSOP (PWP) | 20	2000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TLC084AI
TLC084CD	Active	Production	SOIC (D) | 14	50 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC084C
TLC084CD.B	Active	Production	SOIC (D) | 14	50 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC084C
TLC084CDR	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC084C
TLC084CDR.A	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC084C
TLC084CDR.B	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC084C
TLC084CN	Active	Production	PDIP (N) | 14	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC084C
TLC084CN.A	Active	Production	PDIP (N) | 14	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC084C
TLC084CPWP	Active	Production	HTSSOP (PWP) | 20	70 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	TLC084C
TLC084CPWP.A	Active	Production	HTSSOP (PWP) | 20	70 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	TLC084C
TLC084CPWPR	Active	Production	HTSSOP (PWP) | 20	2000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	TLC084C
TLC084CPWPR.B	Active	Production	HTSSOP (PWP) | 20	2000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	TLC084C
TLC084ID	Active	Production	SOIC (D) | 14	50 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLC084I
TLC084ID.B	Active	Production	SOIC (D) | 14	50 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLC084I
TLC084IDR	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLC084I

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLC084IDR.B	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLC084I
TLC084IDRG4	Active	Production	SOIC (D) | 14	2500 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
TLC084IPWP	Active	Production	HTSSOP (PWP) | 20	70 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TLC084I
TLC084IPWP.B	Active	Production	HTSSOP (PWP) | 20	70 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TLC084I
TLC084IPWPR	Active	Production	HTSSOP (PWP) | 20	2000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TLC084I
TLC084IPWPR.B	Active	Production	HTSSOP (PWP) | 20	2000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TLC084I
TLC085AID	Obsolete	Production	SOIC (D) | 16	-	-	Call TI	Call TI	-40 to 125	TLC085AI
TLC085AIDR	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLC085AI
TLC085AIDR.B	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLC085AI
TLC085AIN	Active	Production	PDIP (N) | 16	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLC085AI
TLC085AIN.B	Active	Production	PDIP (N) | 16	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLC085AI
TLC085AIPWP	Active	Production	HTSSOP (PWP) | 20	70 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TLC085AI
TLC085AIPWP.B	Active	Production	HTSSOP (PWP) | 20	70 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TLC085AI
TLC085CN	Active	Production	PDIP (N) | 16	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC085C
TLC085CN.A	Active	Production	PDIP (N) | 16	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC085C
TLC085CPWP	Active	Production	HTSSOP (PWP) | 20	70 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	TLC085C
TLC085CPWP.A	Active	Production	HTSSOP (PWP) | 20	70 | TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	TLC085C

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

PACKAGE OPTION ADDENDUM

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.
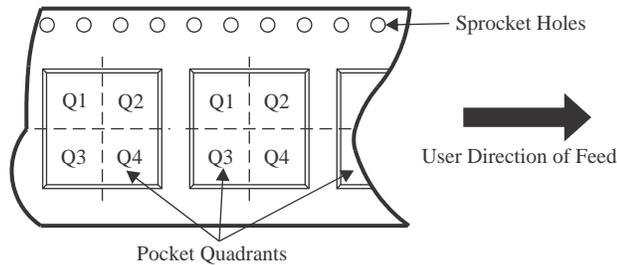
OTHER QUALIFIED VERSIONS OF TLC082, TLC084 :

- Automotive : TLC082-Q1, TLC084-Q1

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLC080AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLC080CDGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLC080CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLC080IDGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLC080IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLC081AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLC081CDGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLC081CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLC081IDGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLC081IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLC082AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLC082CDGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLC082CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLC082IDGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLC082IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLC083CDGQR	HVSSOP	DGQ	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLC083CDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLC084AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLC084AIDRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLC084AIPWPR	HTSSOP	PWP	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TLC084CDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLC084CPWPR	HTSSOP	PWP	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TLC084IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLC084IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLC084IPWPR	HTSSOP	PWP	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TLC085AIDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLC080AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TLC080CDGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
TLC080CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLC080IDGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
TLC080IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLC081AIDR	SOIC	D	8	2500	353.0	353.0	32.0
TLC081CDGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
TLC081CDR	SOIC	D	8	2500	353.0	353.0	32.0
TLC081IDGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
TLC081IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLC082AIDR	SOIC	D	8	2500	353.0	353.0	32.0
TLC082CDGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
TLC082CDR	SOIC	D	8	2500	353.0	353.0	32.0
TLC082IDGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
TLC082IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLC083CDGQR	HVSSOP	DGQ	10	2500	358.0	335.0	35.0
TLC083CDR	SOIC	D	14	2500	350.0	350.0	43.0
TLC084AIDR	SOIC	D	14	2500	353.0	353.0	32.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLC084AIDRG4	SOIC	D	14	2500	353.0	353.0	32.0
TLC084AIPWPR	HTSSOP	PWP	20	2000	350.0	350.0	43.0
TLC084CDR	SOIC	D	14	2500	353.0	353.0	32.0
TLC084CPWPR	HTSSOP	PWP	20	2000	350.0	350.0	43.0
TLC084IDR	SOIC	D	14	2500	353.0	353.0	32.0
TLC084IDR	SOIC	D	14	2500	350.0	350.0	43.0
TLC084IPWPR	HTSSOP	PWP	20	2000	350.0	350.0	43.0
TLC085AIDR	SOIC	D	16	2500	350.0	350.0	43.0

PACKAGE MATERIALS INFORMATION

TUBE

T - Tube height

L - Tube length

W - Tube width

B - Alignment groove width
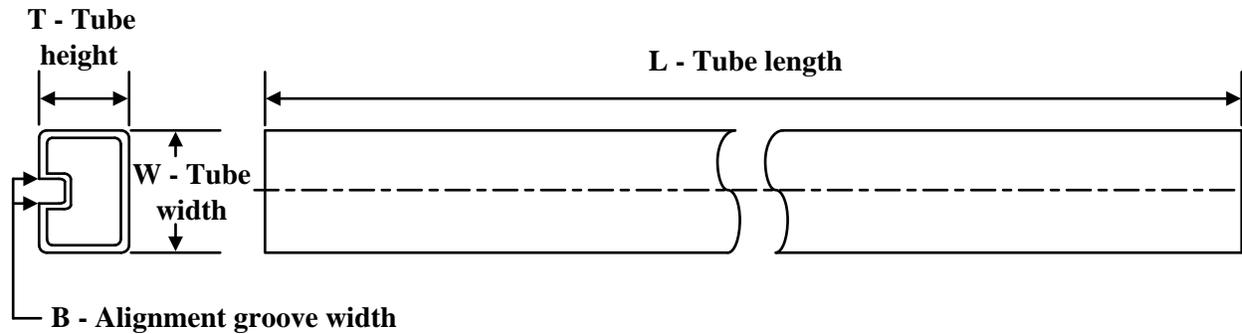
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TLC080AIP	P	PDIP	8	50	506	13.97	11230	4.32
TLC080AIP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLC080ID	D	SOIC	8	75	507	8	3940	4.32
TLC080ID	D	SOIC	8	75	505.46	6.76	3810	4
TLC080ID.A	D	SOIC	8	75	505.46	6.76	3810	4
TLC080ID.A	D	SOIC	8	75	507	8	3940	4.32
TLC081AID	D	SOIC	8	75	505.46	6.76	3810	4
TLC081AID	D	SOIC	8	75	507	8	3940	4.32
TLC081AID.A	D	SOIC	8	75	505.46	6.76	3810	4
TLC081AID.A	D	SOIC	8	75	507	8	3940	4.32
TLC081AIP	P	PDIP	8	50	506	13.97	11230	4.32
TLC081AIP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLC081CD	D	SOIC	8	75	507	8	3940	4.32
TLC081CD.A	D	SOIC	8	75	507	8	3940	4.32
TLC081CP	P	PDIP	8	50	506	13.97	11230	4.32
TLC081CP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLC081ID	D	SOIC	8	75	507	8	3940	4.32
TLC081ID.A	D	SOIC	8	75	507	8	3940	4.32
TLC081IP	P	PDIP	8	50	506	13.97	11230	4.32
TLC081IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLC082AID	D	SOIC	8	75	505.46	6.76	3810	4
TLC082AID	D	SOIC	8	75	507	8	3940	4.32
TLC082AID.A	D	SOIC	8	75	505.46	6.76	3810	4
TLC082AID.A	D	SOIC	8	75	507	8	3940	4.32
TLC082AID.B	D	SOIC	8	75	507	8	3940	4.32
TLC082AID.B	D	SOIC	8	75	505.46	6.76	3810	4
TLC082AIP	P	PDIP	8	50	506	13.97	11230	4.32
TLC082AIP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLC082CD	D	SOIC	8	75	505.46	6.76	3810	4

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TLC082CD	D	SOIC	8	75	507	8	3940	4.32
TLC082CD.A	D	SOIC	8	75	505.46	6.76	3810	4
TLC082CD.A	D	SOIC	8	75	507	8	3940	4.32
TLC082CD.B	D	SOIC	8	75	505.46	6.76	3810	4
TLC082CD.B	D	SOIC	8	75	507	8	3940	4.32
TLC082CP	P	PDIP	8	50	506	13.97	11230	4.32
TLC082CP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLC082CP.B	P	PDIP	8	50	506	13.97	11230	4.32
TLC082ID	D	SOIC	8	75	507	8	3940	4.32
TLC082ID	D	SOIC	8	75	505.46	6.76	3810	4
TLC082ID.A	D	SOIC	8	75	505.46	6.76	3810	4
TLC082ID.A	D	SOIC	8	75	507	8	3940	4.32
TLC082ID.B	D	SOIC	8	75	507	8	3940	4.32
TLC082ID.B	D	SOIC	8	75	505.46	6.76	3810	4
TLC082IP	P	PDIP	8	50	506	13.97	11230	4.32
TLC082IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLC083AID	D	SOIC	14	50	505.46	6.76	3810	4
TLC083AID.A	D	SOIC	14	50	505.46	6.76	3810	4
TLC083CN	N	PDIP	14	25	506	13.97	11230	4.32
TLC083CN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLC083IN	N	PDIP	14	25	506	13.97	11230	4.32
TLC083IN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLC084AID	D	SOIC	14	50	505.46	6.76	3810	4
TLC084AID	D	SOIC	14	50	506.6	8	3940	4.32
TLC084AID.B	D	SOIC	14	50	505.46	6.76	3810	4
TLC084AID.B	D	SOIC	14	50	506.6	8	3940	4.32
TLC084AIN	N	PDIP	14	25	506	13.97	11230	4.32
TLC084AIN.B	N	PDIP	14	25	506	13.97	11230	4.32
TLC084AIPWP	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TLC084AIPWP.B	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TLC084CD	D	SOIC	14	50	505.46	6.76	3810	4
TLC084CD	D	SOIC	14	50	506.6	8	3940	4.32
TLC084CD.B	D	SOIC	14	50	505.46	6.76	3810	4
TLC084CD.B	D	SOIC	14	50	506.6	8	3940	4.32
TLC084CN	N	PDIP	14	25	506	13.97	11230	4.32
TLC084CN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLC084CPWP	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TLC084CPWP.A	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TLC084ID	D	SOIC	14	50	505.46	6.76	3810	4
TLC084ID	D	SOIC	14	50	506.6	8	3940	4.32
TLC084ID.B	D	SOIC	14	50	505.46	6.76	3810	4
TLC084ID.B	D	SOIC	14	50	506.6	8	3940	4.32
TLC084IPWP	PWP	HTSSOP	20	70	530	10.2	3600	3.5

PACKAGE MATERIALS INFORMATION

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TLC084IPWP.B	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TLC085AIN	N	PDIP	16	25	506	13.97	11230	4.32
TLC085AIN.B	N	PDIP	16	25	506	13.97	11230	4.32
TLC085AIPWP	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TLC085AIPWP.B	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TLC085CN	N	PDIP	16	25	506	13.97	11230	4.32
TLC085CN.A	N	PDIP	16	25	506	13.97	11230	4.32
TLC085CPWP	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TLC085CPWP.A	PWP	HTSSOP	20	70	530	10.2	3600	3.5

A

PIN 1 ID
AREA

$\frac{6.2}{5.8}$ TYP

1

14

12X 1.27

2X 7.62

$\frac{8.75}{8.55}$
NOTE 3

7

8

14X $\frac{0.51}{0.31}$

$\bigoplus$ 0.25 Ⓜ C A B

B

$\frac{4.0}{3.8}$
NOTE 4

C

SEATING PLANE

◯ 0.1 C

1.75 MAX

SEE DETAIL A

$\frac{0.25}{0.13}$ TYP

0.25
GAGE PLANE

0° - 8°

$\frac{1.27}{0.40}$

$\frac{0.25}{0.10}$

DETAIL A
TYPICAL
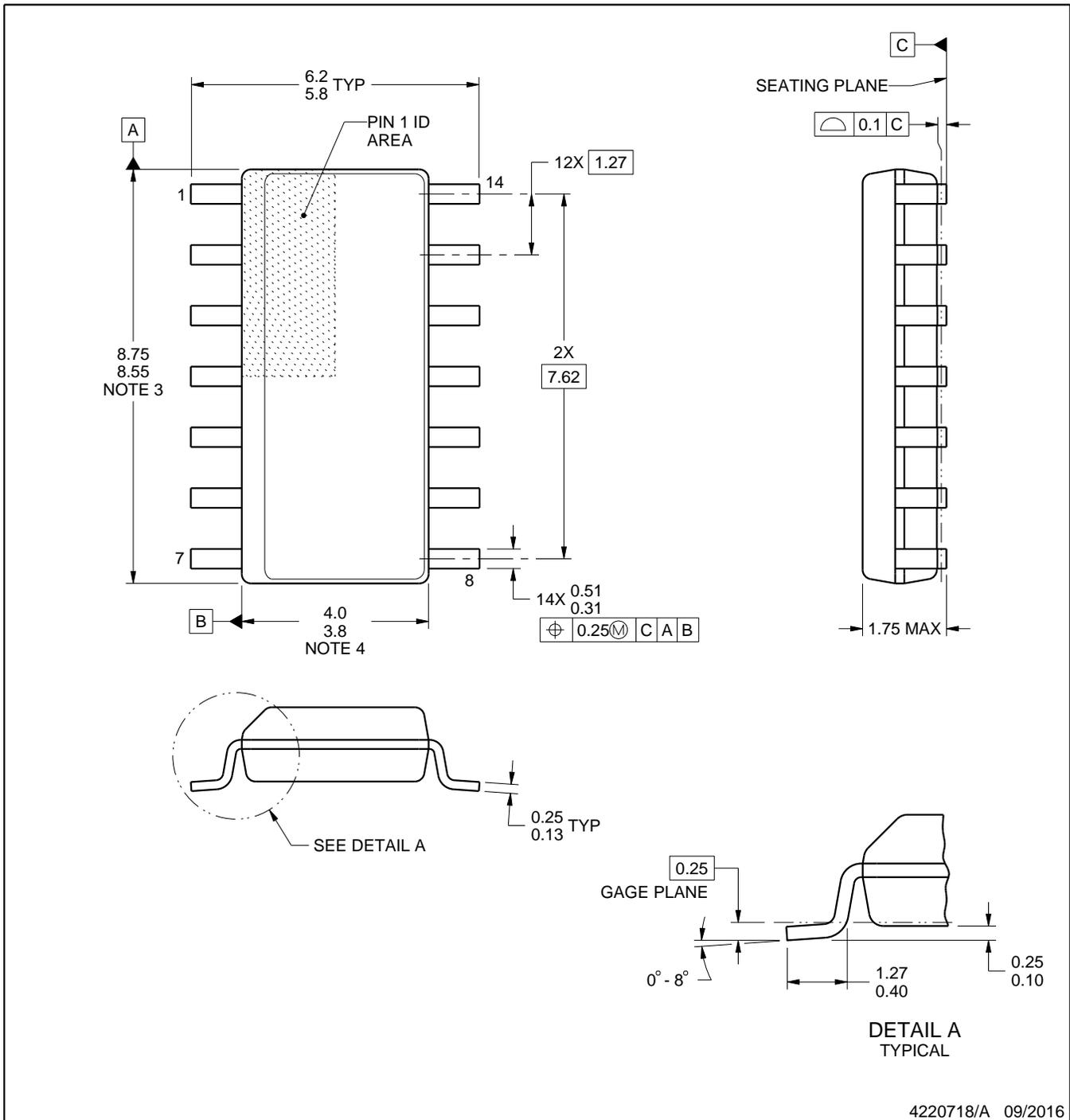
4220718/A 09/2016

NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
   per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
   exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
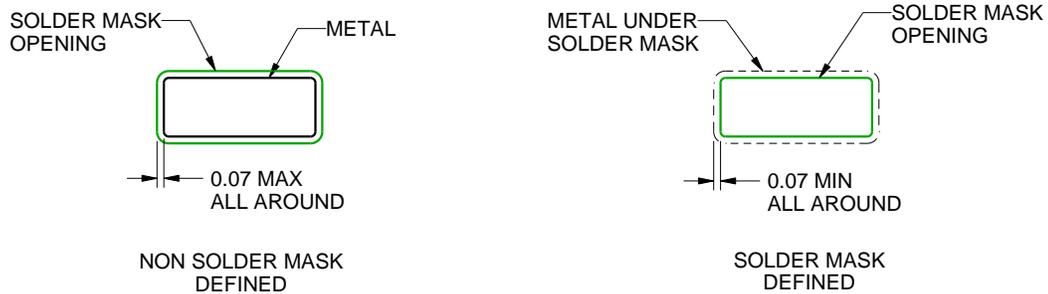5. Reference JEDEC registration MS-012, variation AB.

TEXAS INSTRUMENTS
www.ti.com

D0014A

14X (1.55)

1

14X (0.6)

12X (1.27)

SYMM

14

SYMM

7

8

(R0.05)
TYP

(5.4)
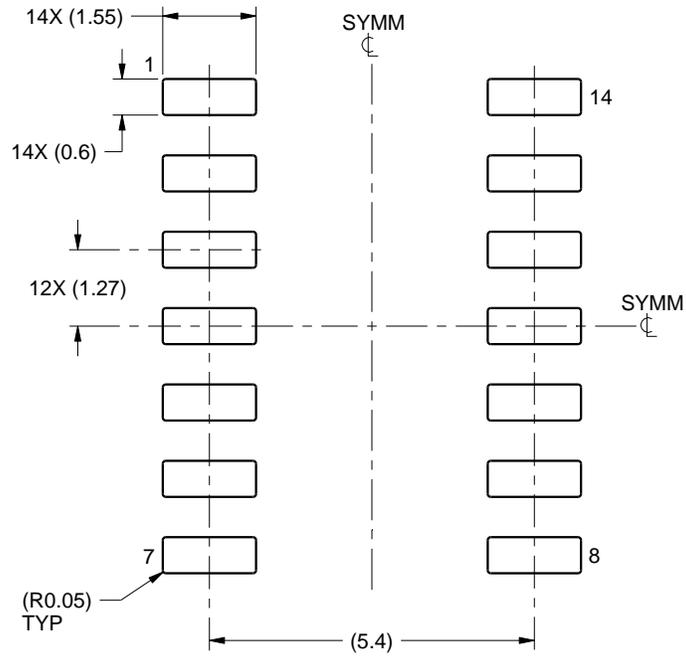
LAND PATTERN EXAMPLE
SCALE:8X

SOLDER MASK
OPENING

METAL

0.07 MAX
ALL AROUND

NON SOLDER MASK
DEFINED

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

0.07 MIN
ALL AROUND

SOLDER MASK
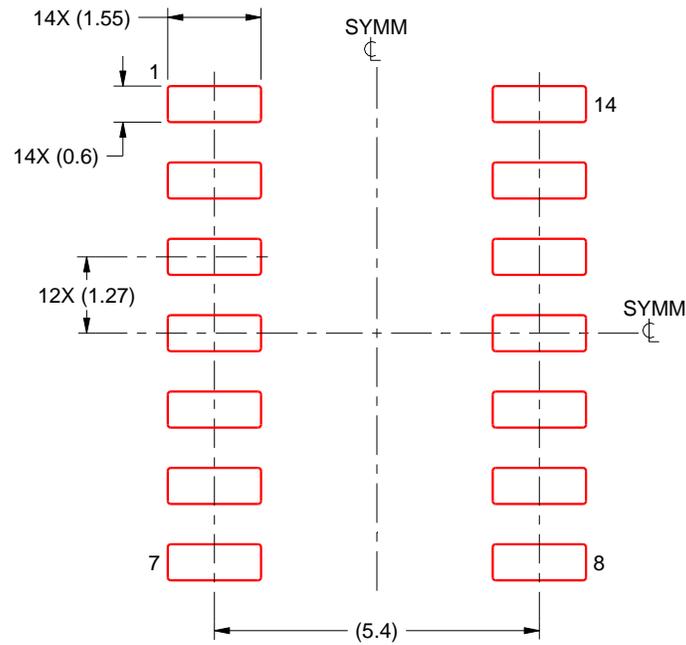DEFINED

SOLDER MASK DETAILS

4220718/A   09/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

14X (1.55)

SYMM

1

14

14X (0.6)

12X (1.27)

SYMM

7

8

(5.4)

SOLDER PASTE EXAMPLE
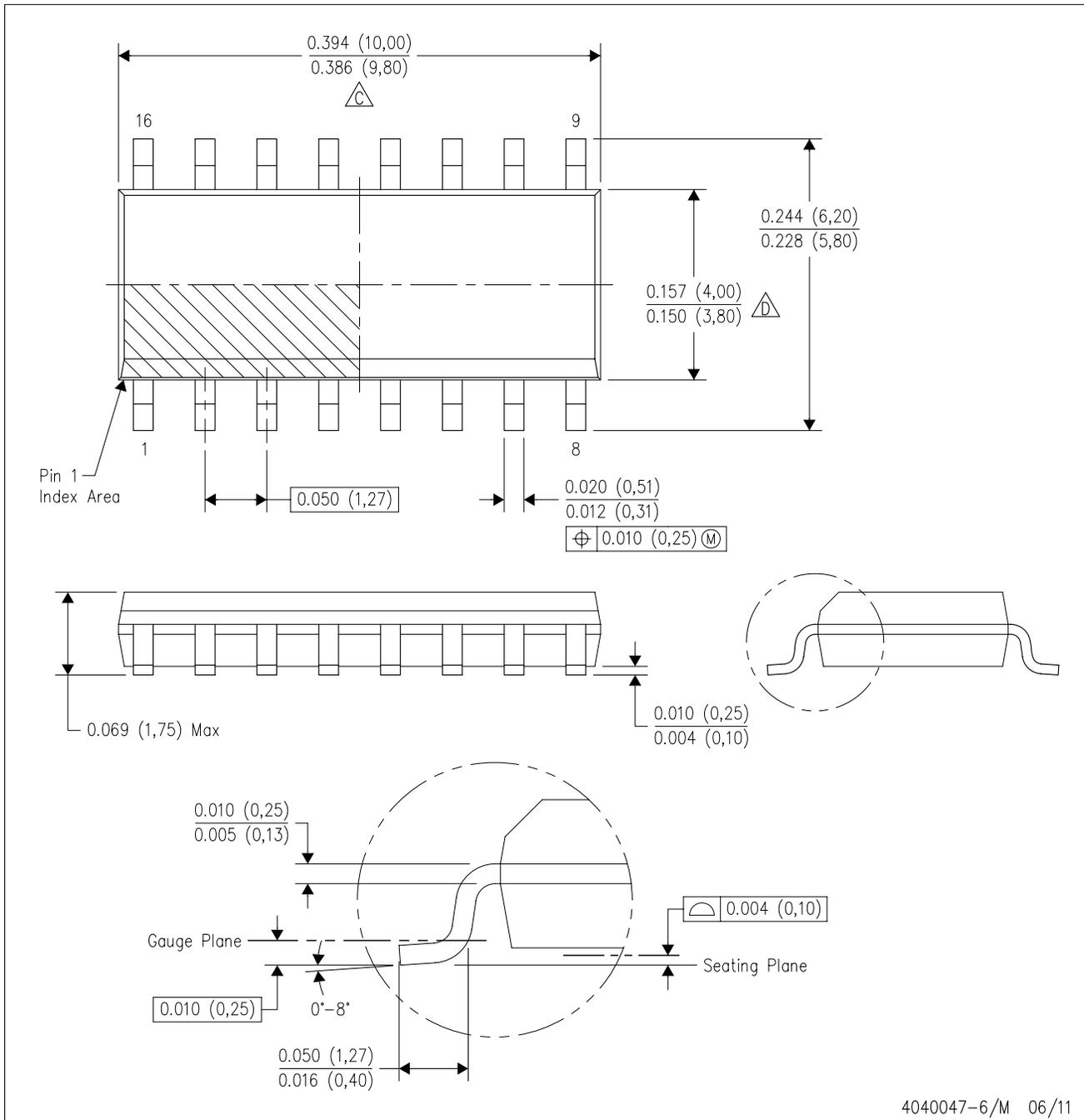BASED ON 0.125 mm THICK STENCIL
SCALE:8X

4220718/A   09/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

D (R−PDSO−G16)   PLASTIC SMALL OUTLINE

0.394 (10,00)
0.386 (9,80)
△C

16   9

0.244 (6,20)
0.228 (5,80)

0.157 (4,00)
0.150 (3,80) △D

1   8

Pin 1
Index Area

0.050 (1,27)

0.020 (0,51)
0.012 (0,31)

⊕ | 0.010 (0,25) Ⓜ

0.069 (1,75) Max

0.010 (0,25)
0.004 (0,10)

0.010 (0,25)
0.005 (0,13)

⌂ | 0.004 (0,10)

Gauge Plane

Seating Plane

0.010 (0,25)   0°–8°

0.050 (1,27)
0.016 (0,40)

4040047–6/M   06/11

NOTES: A. All linear dimensions are in inches (millimeters).
         B. This drawing is subject to change without notice.
        △C Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall
             not exceed 0.006 (0,15) each side.
        △D Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
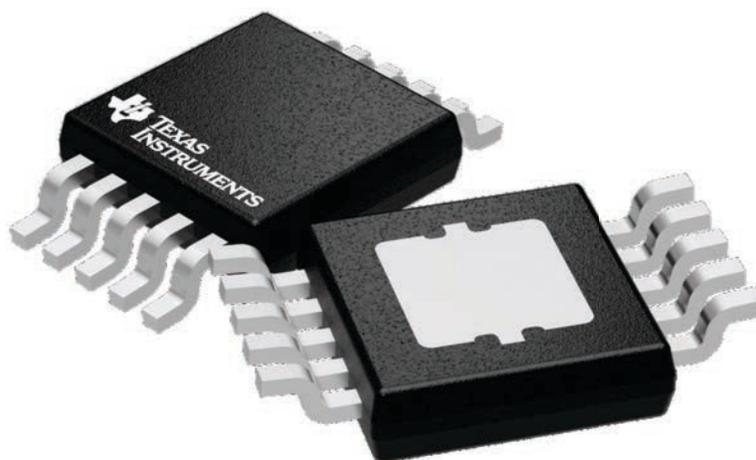   E. Reference JEDEC MS–012 variation AC.

DGQ 10

PowerPAD™ HVSSOP - 1.1 mm max height

3 x 3, 0.5 mm pitch

PLASTIC SMALL OUTLINE

Images above are just a representation of the package family, actual package may vary.
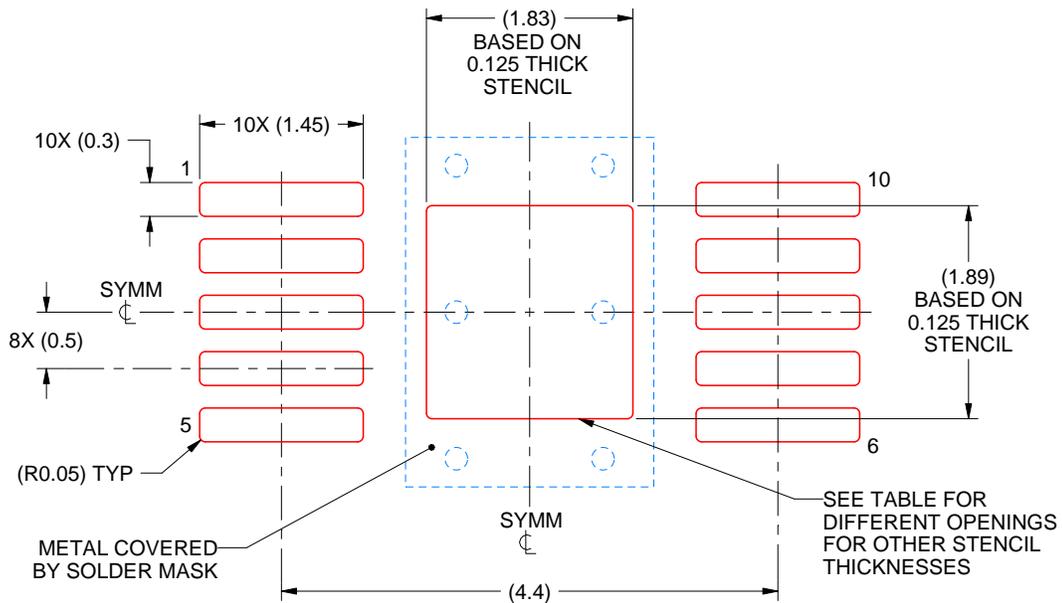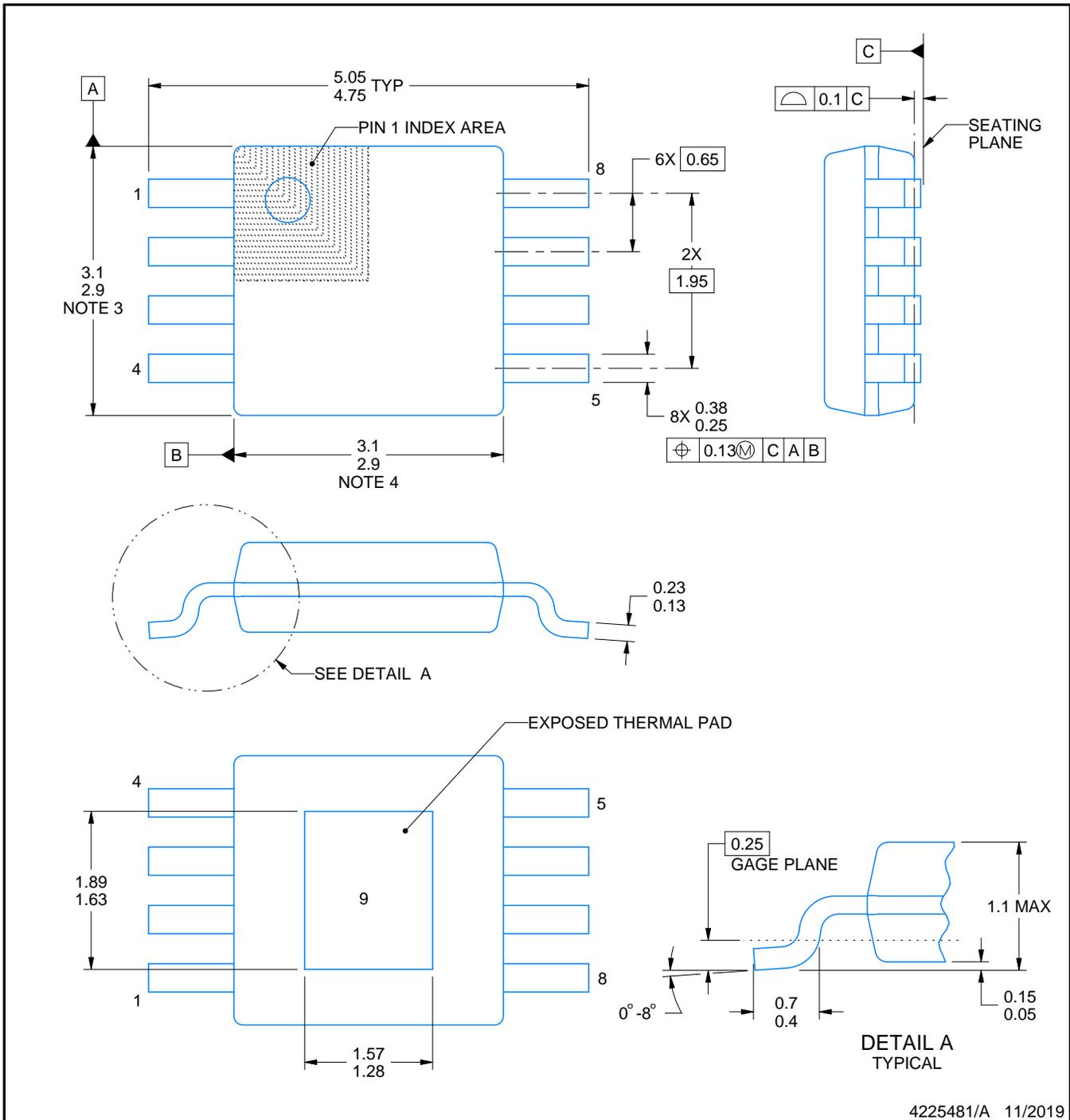Refer to the product data sheet for package details.

4224775/A

C

SEATING PLANE

$\triangle$ 0.1 C

$\frac{5.05}{4.75}$ TYP

A

PIN 1 ID AREA

1

$\frac{3.1}{2.9}$ NOTE 3

5

8X 0.5

10

2X 2

6

10X $\frac{0.27}{0.17}$

$\oplus$ 0.08 Ⓜ C A B

B

$\frac{3.1}{2.9}$ NOTE 4

1.1 MAX

$\frac{0.23}{0.13}$ TYP

SEE DETAIL A

EXPOSED THERMAL PAD

5

$\frac{1.89}{1.69}$

1

6

10

$\frac{1.83}{1.63}$

0.25

GAGE PLANE

0° - 8°

$\frac{0.7}{0.4}$

$\frac{0.15}{0.05}$

DETAIL A
TYPICAL

4218842/B   04/2024

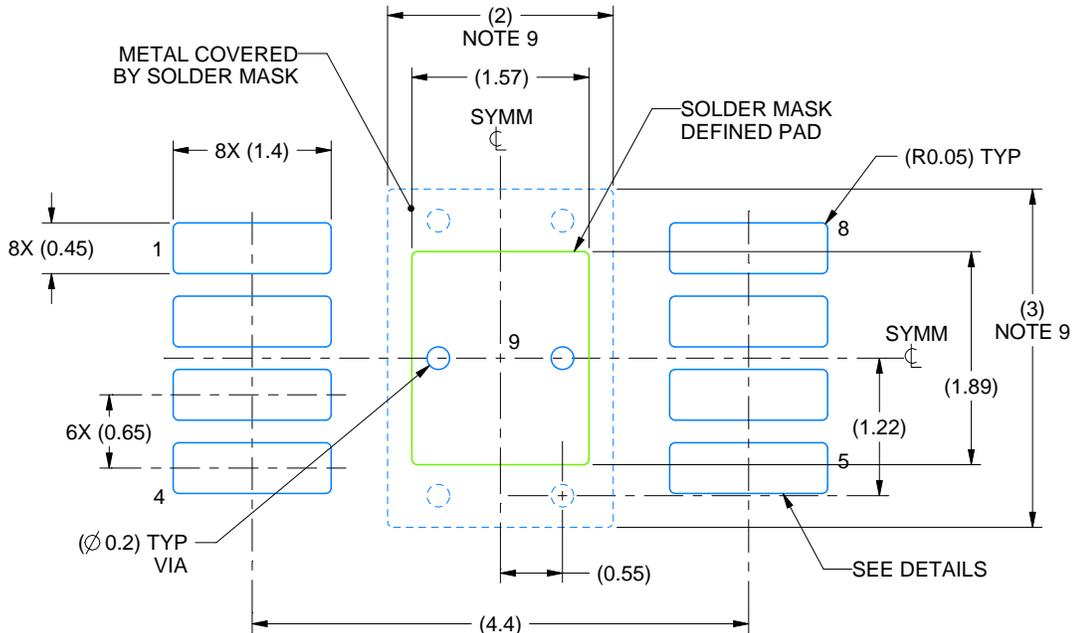PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
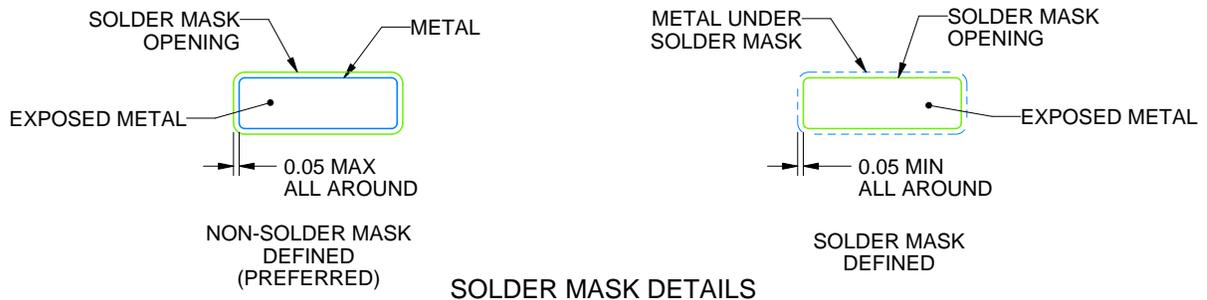5. Reference JEDEC registration MO-187, variation BA-T.

DGQ0010D

PLASTIC SMALL OUTLINE

LAND PATTERN EXAMPLE
SCALE:15X

(2.2)
NOTE 9

(1.83)
SOLDER MASK
OPENING

SOLDER MASK
DEFINED PAD

SEE DETAILS

10X (1.45)

10X (0.3)

1

SYMM
℄

8X (0.5)

5

(R0.05) TYP

(Ø 0.2) TYP
VIA

SYMM
℄

(1.3) TYP

10

(1.3)
TYP

(1.89)
SOLDER MASK
OPENING

(3.1)
NOTE 9

6

METAL COVERED
BY SOLDER MASK

(4.4)

SOLDER MASK
OPENING

METAL

0.05 MAX
ALL AROUND

NON SOLDER MASK
DEFINED

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

0.05 MIN
ALL AROUND

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

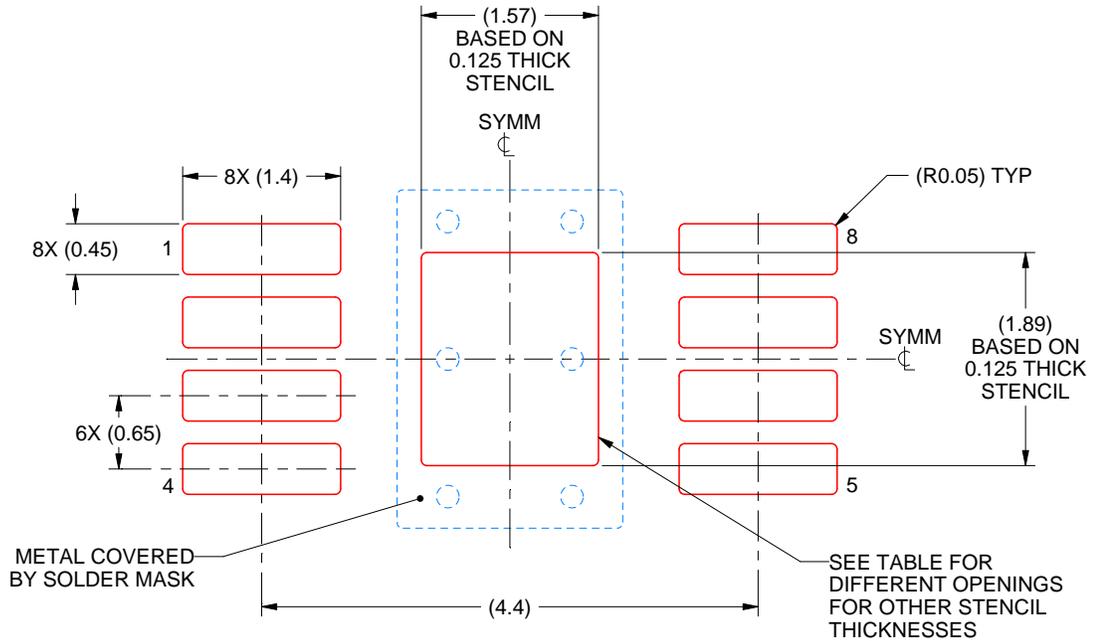4218842/B 04/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
9. Size of metal pad may vary due to creepage requirement.

DGQ0010D

(1.83)
BASED ON
0.125 THICK
STENCIL

10X (1.45)

10X (0.3)

1

10

SYMM
℄

(1.89)
BASED ON
0.125 THICK
STENCIL

8X (0.5)

5

6

(R0.05) TYP

SYMM
℄

SEE TABLE FOR
DIFFERENT OPENINGS
FOR OTHER STENCIL
THICKNESSES

METAL COVERED
BY SOLDER MASK

(4.4)

SOLDER PASTE EXAMPLE
EXPOSED PAD
100% PRINTED SOLDER COVERAGE BY AREA
SCALE:15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	2.05 X 2.11
0.125	1.83 X 1.89 (SHOWN)
0.150	1.67 X 1.73
0.175	1.55 X 1.60

4218842/B   04/2024

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

DGN 8

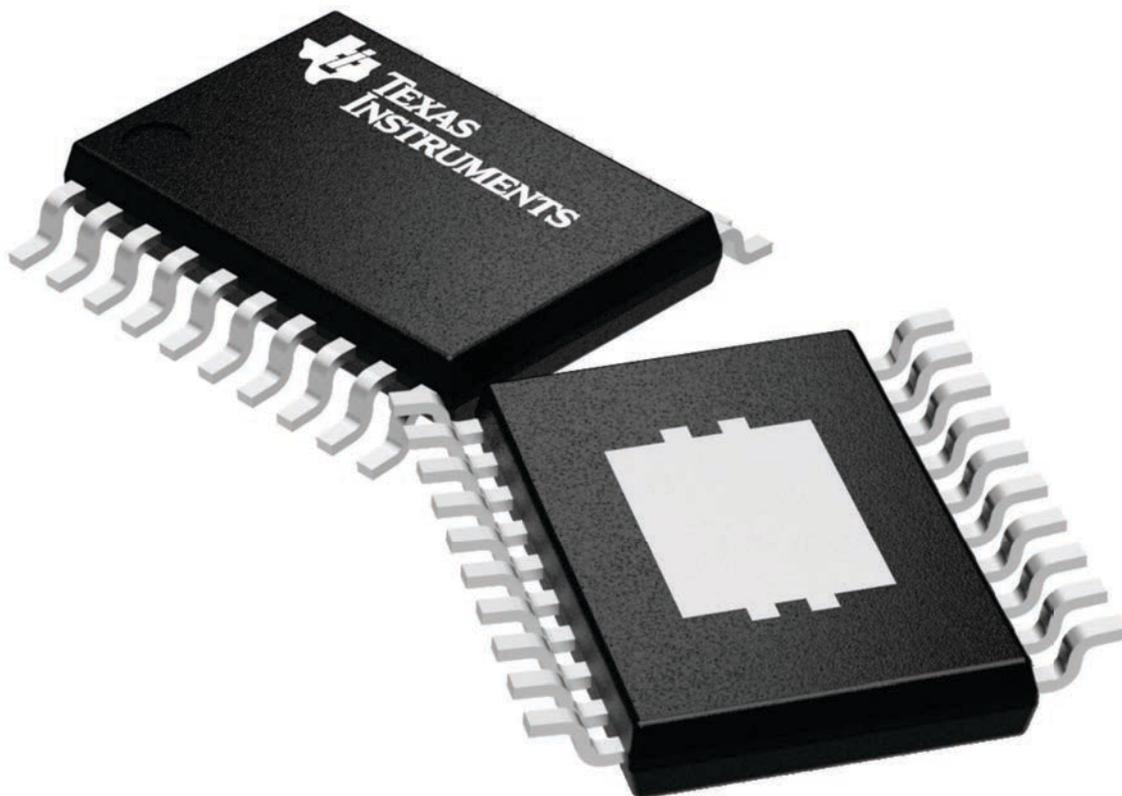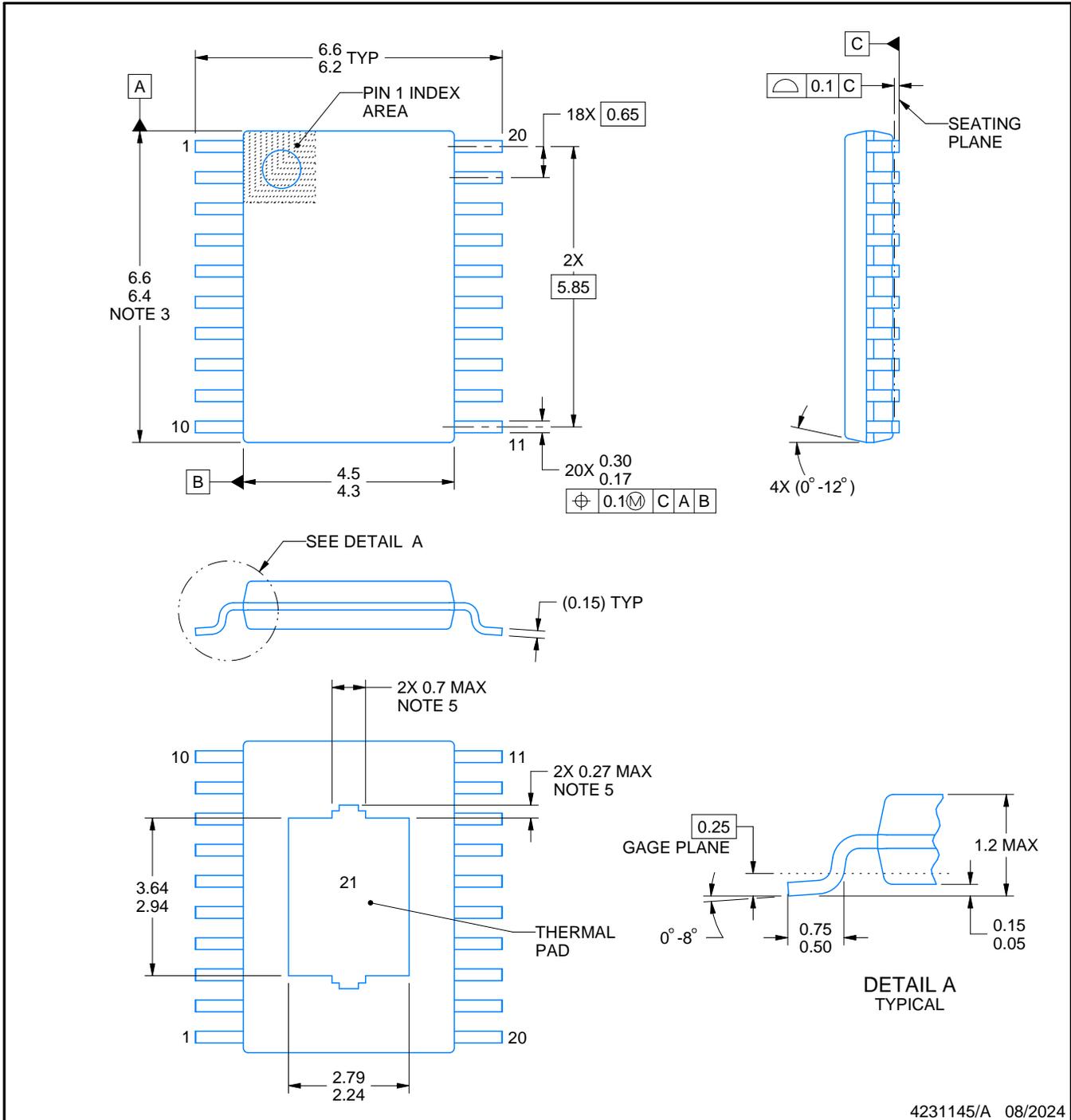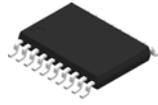PowerPAD™ HVSSOP - 1.1 mm max height

3 x 3, 0.65 mm pitch

SMALL OUTLINE PACKAGE

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4225482/B

5.05 / 4.75 TYP

PIN 1 INDEX AREA

C

◯ 0.1 C

SEATING PLANE

A

1

8

6X 0.65

2X 1.95

3.1 / 2.9 NOTE 3

4

5

8X 0.38 / 0.25

⊕ 0.13 Ⓜ C A B

B

3.1 / 2.9 NOTE 4

0.23 / 0.13

SEE DETAIL A

EXPOSED THERMAL PAD

4

5

1.89 / 1.63

9

8

1

1.57 / 1.28

0.25 GAGE PLANE

1.1 MAX

0.7 / 0.4

0.15 / 0.05

0° -8°

DETAIL A
TYPICAL
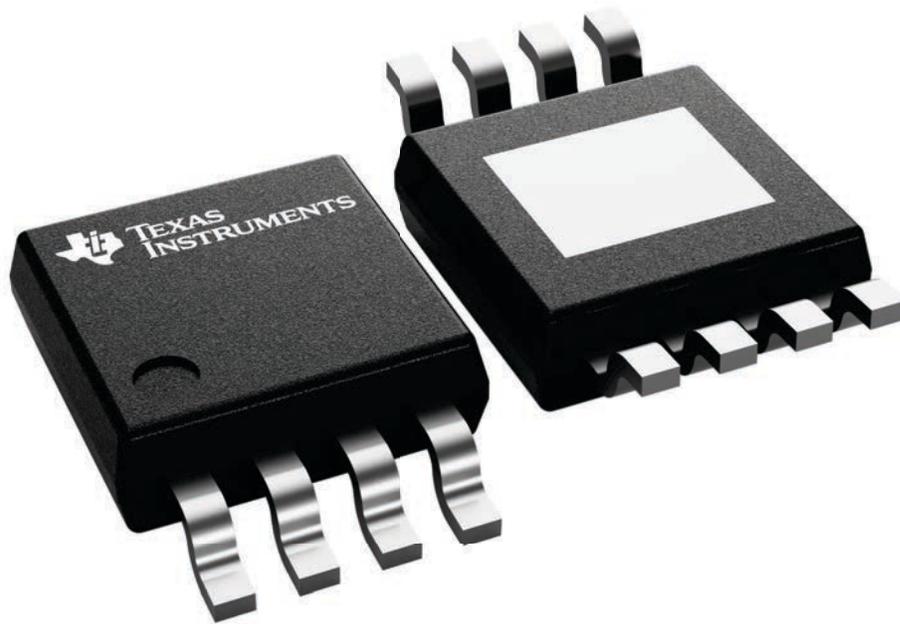
4225481/A   11/2019

PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

METAL COVERED
BY SOLDER MASK

(2)
NOTE 9

(1.57)

SYMM

SOLDER MASK
DEFINED PAD

(R0.05) TYP

8X (1.4)

8X (0.45)   1

8

9

SYMM

(3)
NOTE 9

(1.89)

6X (0.65)

(1.22)

4

5

(∅ 0.2) TYP
VIA

(0.55)

SEE DETAILS

(4.4)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

SOLDER MASK
OPENING

METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

0.05 MIN
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

SOLDER MASK DETAILS

SOLDER MASK
DEFINED

4225481/A   11/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

(1.57)
BASED ON
0.125 THICK
STENCIL

SYMM

8X (1.4)

8X (0.45)

(R0.05) TYP

(1.89)
BASED ON
0.125 THICK
STENCIL

SYMM

6X (0.65)

METAL COVERED
BY SOLDER MASK

SEE TABLE FOR
DIFFERENT OPENINGS
FOR OTHER STENCIL
THICKNESSES

(4.4)

SOLDER PASTE EXAMPLE
EXPOSED PAD 9:
100% PRINTED SOLDER COVERAGE BY AREA
SCALE: 15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	1.76 X 2.11
0.125	1.57 X 1.89 (SHOWN)
0.15	1.43 X 1.73
0.175	1.33 X 1.60

4225481/A   11/2019

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4224669/A

6.6 / 6.2 TYP

A

PIN 1 INDEX AREA

18X 0.65

1

20

6.6 / 6.4 NOTE 3

2X 5.85

10

11

B

4.5 / 4.3

20X 0.30 / 0.17

⊕ 0.1Ⓜ C A B

C

◯ 0.1 C

SEATING PLANE

4X (0°-12°)

SEE DETAIL A

(0.15) TYP

2X 0.7 MAX NOTE 5

10

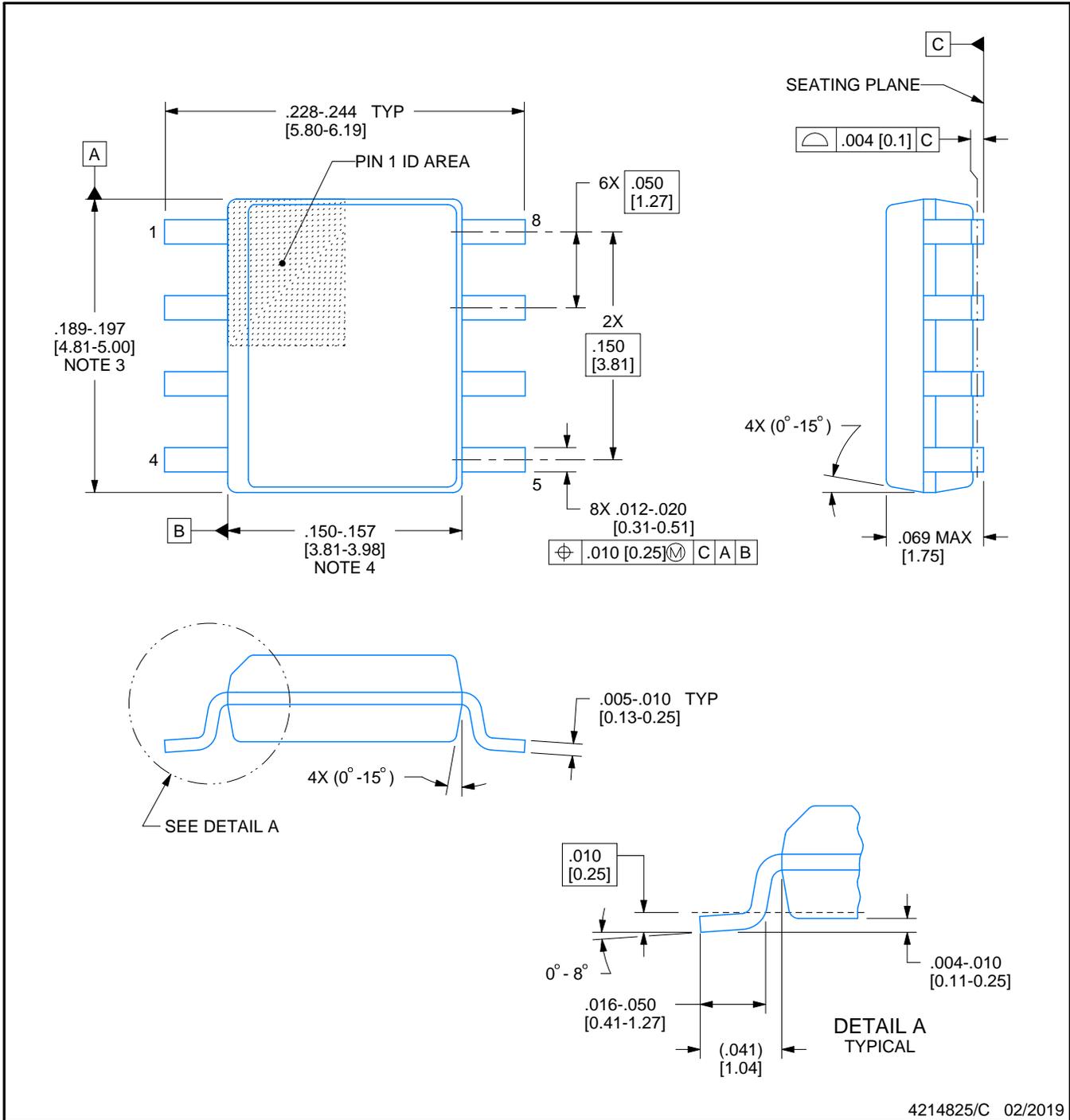11

2X 0.27 MAX NOTE 5

3.64 / 2.94

21

THERMAL PAD

1

20

2.79 / 2.24

0.25
GAGE PLANE

1.2 MAX

0°-8°

0.75 / 0.50

0.15 / 0.05

DETAIL A
TYPICAL

4231145/A   08/2024

PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-153.
5. Features may differ or may not be present.

(3.4)
NOTE 9

(2.79)

20X (1.5)

SYMM

METAL COVERED
BY SOLDER MASK

1

20

20X (0.45)

(R0.05) TYP

(1.3)
TYP

(6.5)
NOTE 9

SYMM

21

(3.64)

SOLDER MASK
DEFINED PAD

18X (0.65)

10

11

(Ø 0.2) TYP
VIA

(1.3) TYP

SEE DETAILS

(5.8)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

SOLDER MASK
OPENING

METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

0.05 MIN
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4231145/A   08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
9. Size of metal pad may vary due to creepage requirement.
10. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.

PWP0020W

PowerPAD™ TSSOP - 1.2 mm max height

SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X
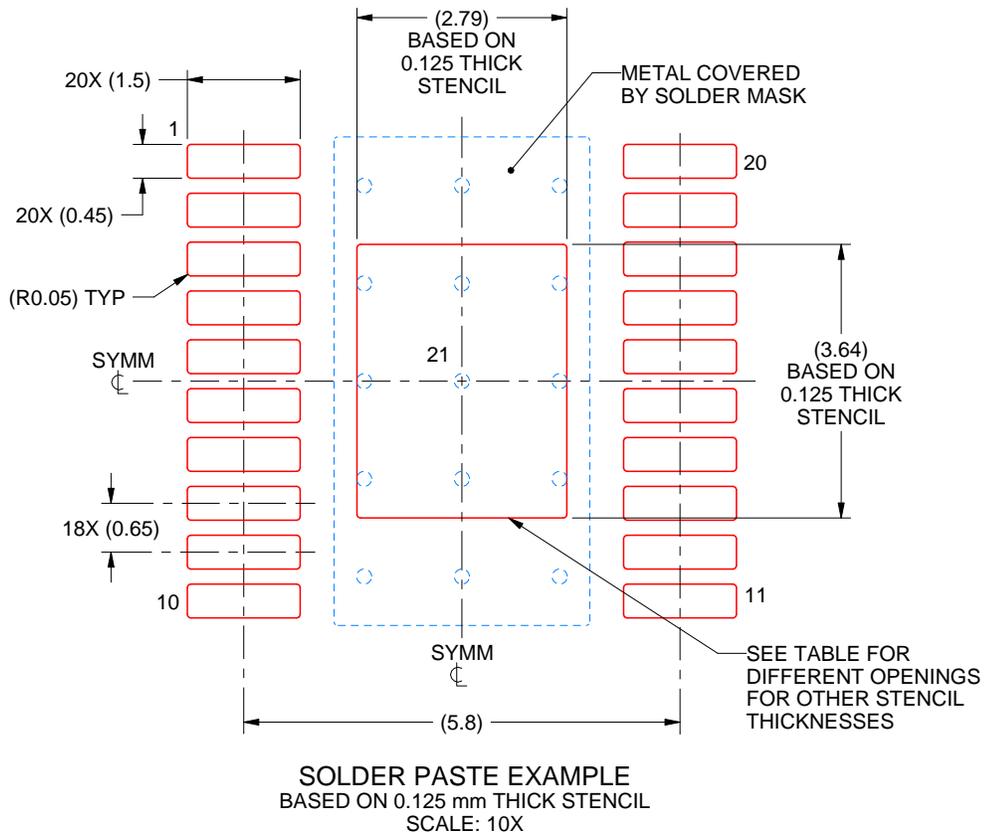
STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	3.12 X 4.07
0.125	2.79 X 3.64 (SHOWN)
0.15	2.55 X 3.32
0.175	2.36 X 3.08

4231145/A   08/2024
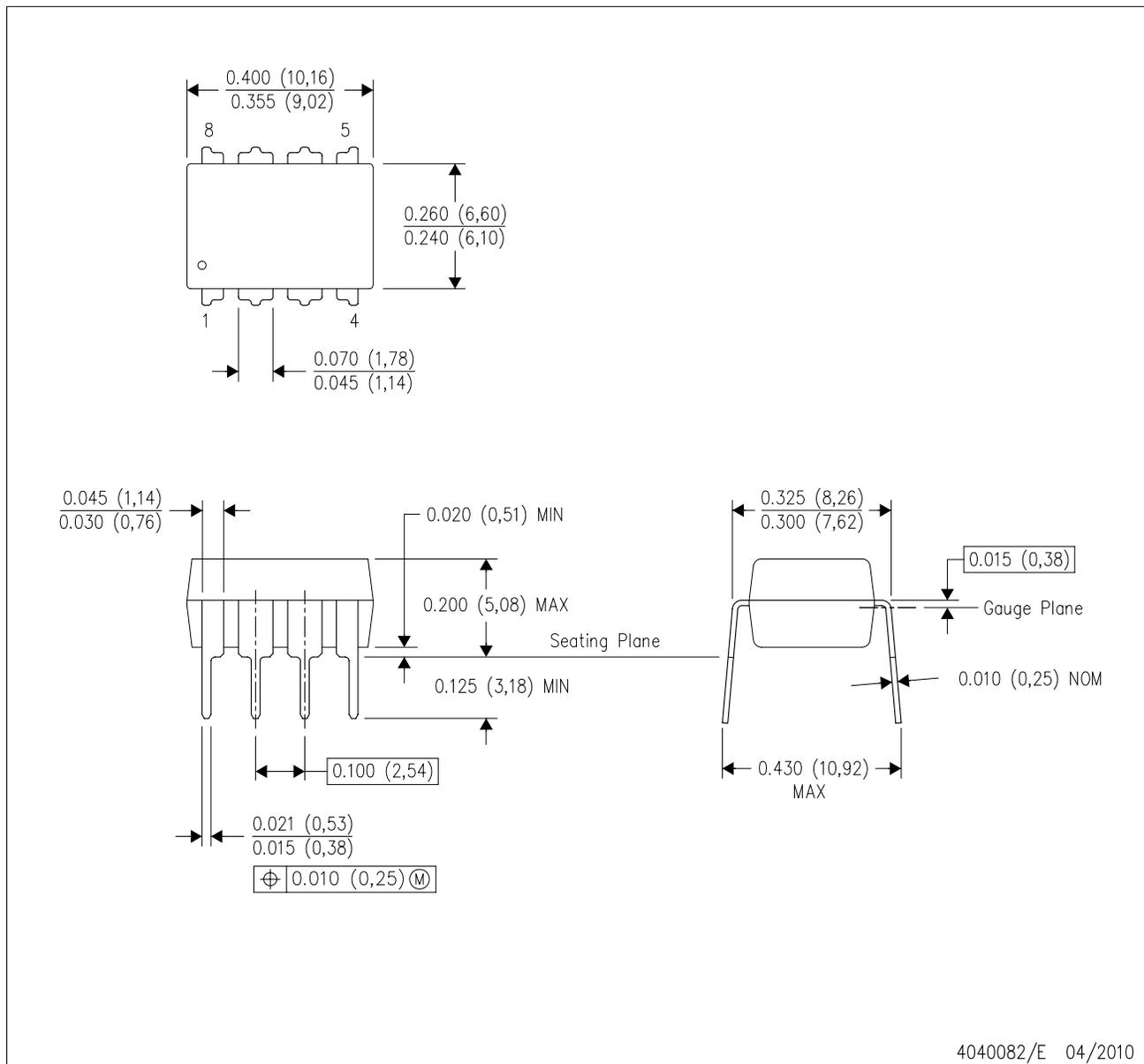
NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.
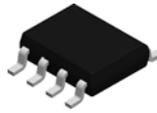
.228-.244   TYP
[5.80-6.19]

PIN 1 ID AREA

.189-.197
[4.81-5.00]
NOTE 3

6X .050
[1.27]

2X
.150
[3.81]

8X .012-.020
[0.31-0.51]

⊕ .010 [0.25] Ⓜ C A B

.150-.157
[3.81-3.98]
NOTE 4

SEATING PLANE

⌒ .004 [0.1] C

4X (0°-15°)

.069 MAX
[1.75]

SEE DETAIL A

4X (0°-15°)

.005-.010   TYP
[0.13-0.25]

.010
[0.25]

0°- 8°

.016-.050
[0.41-1.27]

(.041)
[1.04]

.004-.010
[0.11-0.25]

DETAIL A
TYPICAL

4214825/C   02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches.
   Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
   exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

8X (.061)
[1.55]

SYMM
₵

SEE
DETAILS

1

8X (.024)
[0.6]

8

SYMM
₵

(R.002) TYP
[0.05]

4

5

6X (.050)
[1.27]

(.213)
[5.4]

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X

METAL

SOLDER MASK
OPENING

SOLDER MASK
OPENING

METAL UNDER
SOLDER MASK

EXPOSED
METAL

EXPOSED
METAL

.0028 MAX
[0.07]
ALL AROUND

.0028 MIN
[0.07]
ALL AROUND
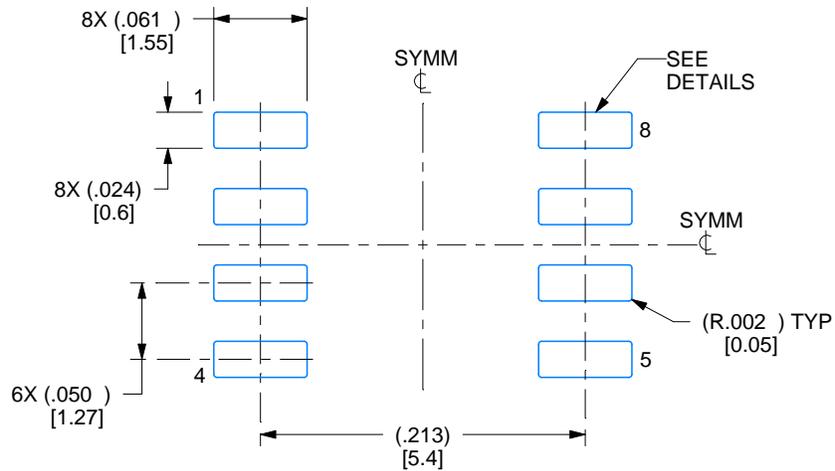
NON SOLDER MASK
DEFINED

SOLDER MASK
DEFINED
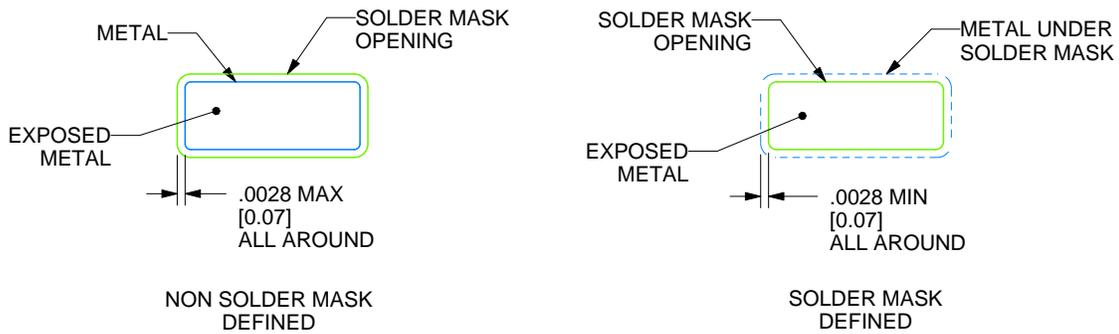
SOLDER MASK DETAILS

4214825/C   02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
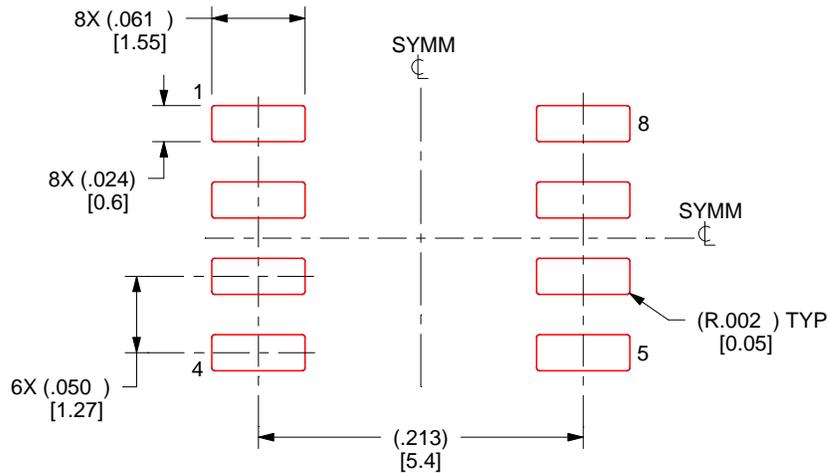
SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R−PDIP−T8)   PLASTIC DUAL−IN−LINE PACKAGE

0.400 (10,16)
0.355 (9,02)

8   5

0.260 (6,60)
0.240 (6,10)

1   4

0.070 (1,78)
0.045 (1,14)

0.045 (1,14)
0.030 (0,76)

0.020 (0,51) MIN

0.200 (5,08) MAX

Seating Plane

0.125 (3,18) MIN

0.100 (2,54)

0.021 (0,53)
0.015 (0,38)

⊕ 0.010 (0,25) Ⓜ

0.325 (8,26)
0.300 (7,62)

0.015 (0,38)

Gauge Plane

0.010 (0,25) NOM

0.430 (10,92)
MAX

4040082/E 04/2010

NOTES: A.   All linear dimensions are in inches (millimeters).
         B.   This drawing is subject to change without notice.
         C.   Falls within JEDEC MS−001 variation BA.

N (R−PDIP−T**)
16 PINS SHOWN
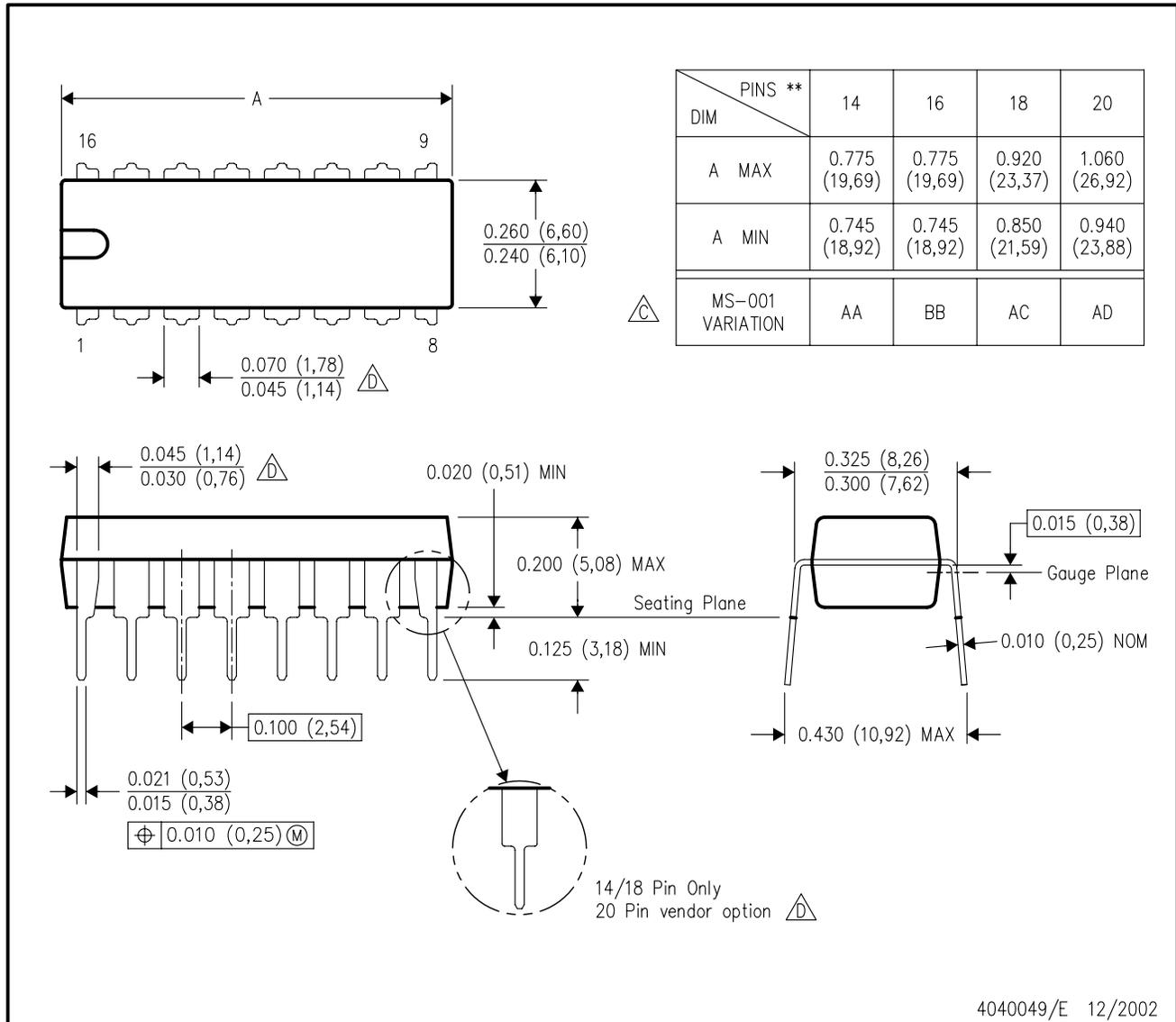
PLASTIC DUAL−IN−LINE PACKAGE

DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS−001 VARIATION	AA	BB	AC	AD

0.260 (6,60)
0.240 (6,10)

0.070 (1,78)
0.045 (1,14)

0.045 (1,14)
0.030 (0,76)

0.020 (0,51) MIN

0.200 (5,08) MAX

Seating Plane

0.125 (3,18) MIN

0.100 (2,54)

0.021 (0,53)
0.015 (0,38)

⊕ 0.010 (0,25) Ⓜ

0.325 (8,26)
0.300 (7,62)

0.015 (0,38)

Gauge Plane

0.010 (0,25) NOM

0.430 (10,92) MAX

14/18 Pin Only
20 Pin vendor option

4040049/E 12/2002

NOTES: A. All linear dimensions are in inches (millimeters).
        B. This drawing is subject to change without notice.
        C. Falls within JEDEC MS−001, except 18 and 20 pin minimum body length (Dim A).
        D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

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